

# Exciton dynamics and valley-contrasting properties in heterostructures based on atomically-thin semiconductors

Stéphane BERCIAUD

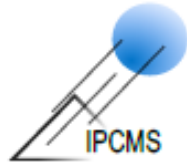
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Workshop on Chiral Optical Modes, Aussois, Nov. 27, 2018



# Acknowledgements



*Etienne Lorchat  
PhD student (2015-)*



*Guillaume Froehlicher  
PhD student (2013-16)*



*ISIS*

*Stefano Azzini, Thibault Chervy  
Thomas Ebbesen, Cyriaque Genet*

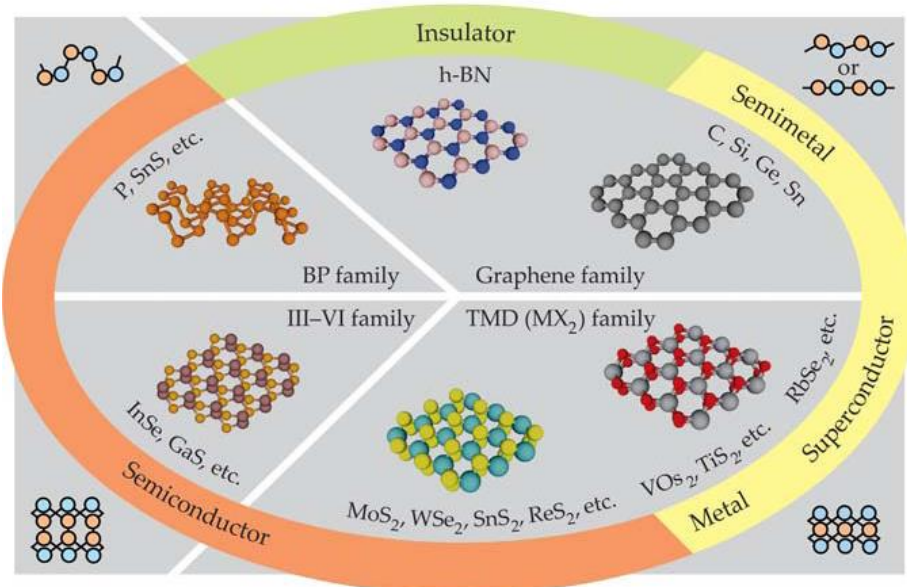


*Cédric Robert,  
Delphine Lagarde,  
Xavier Marie*



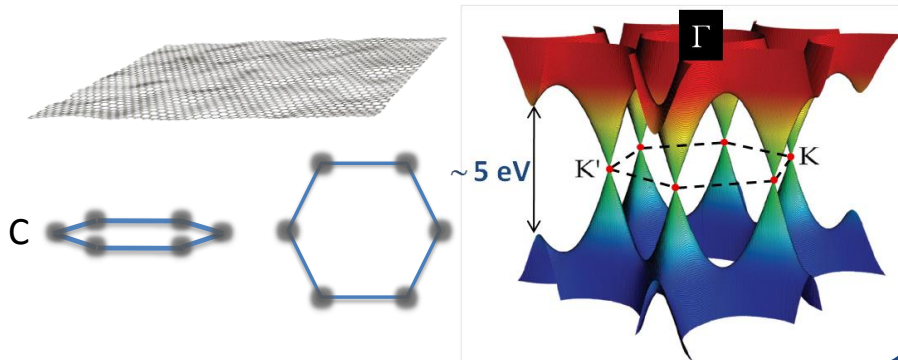
*Takashi Taniguchi  
Kenji Watanabe*

# Entering "Flatland"

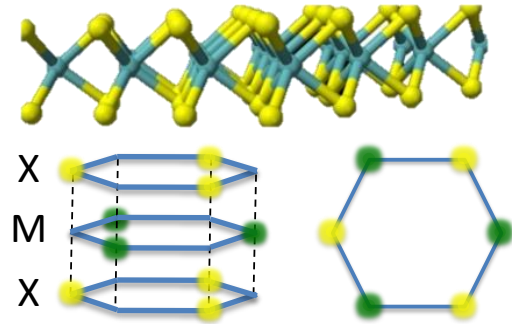


Ajayan, Kim, Banerjee - Physics Today (2016)

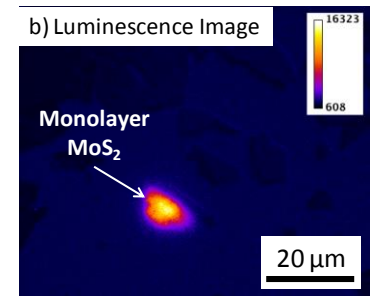
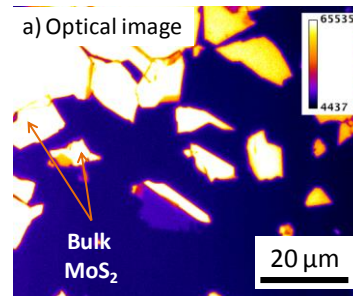
## Graphene (semimetal)



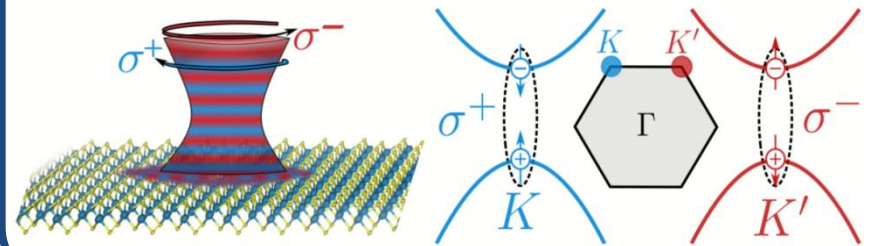
## 2H-TMD (semiconductors) M= Mo, W X= S, Se, Te



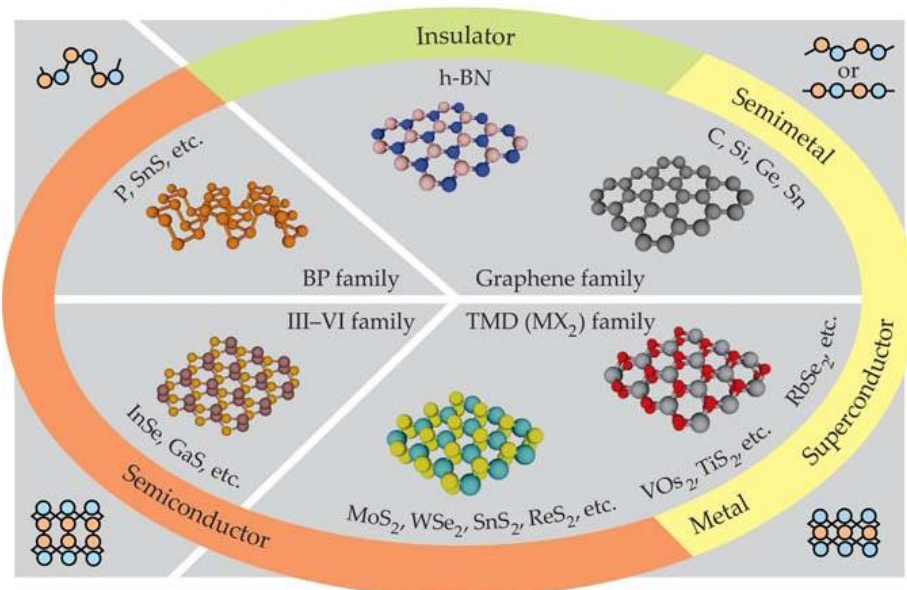
Direct bandgap emission



Helicity-dependent valley addressability

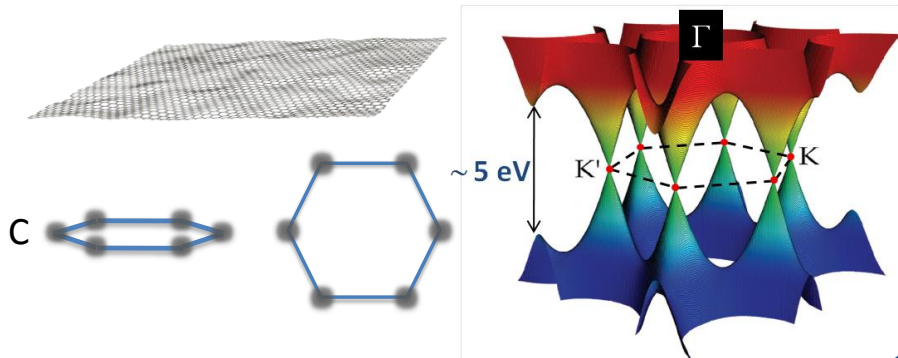


# Entering "Flatland"

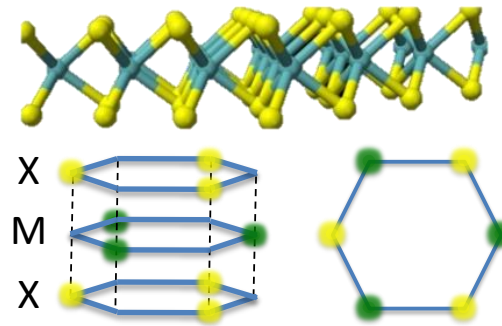


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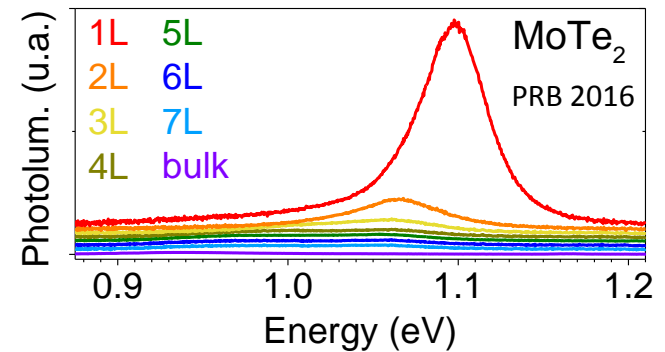
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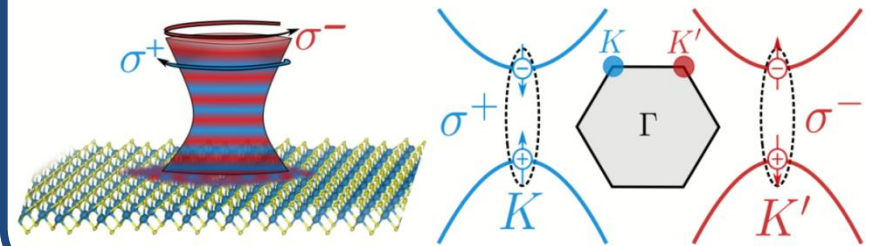
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### Direct bandgap emission



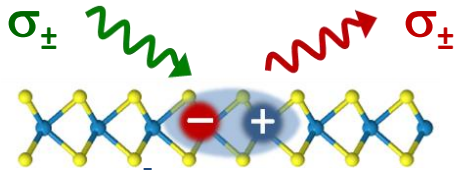
### Helicity-dependent valley addressability



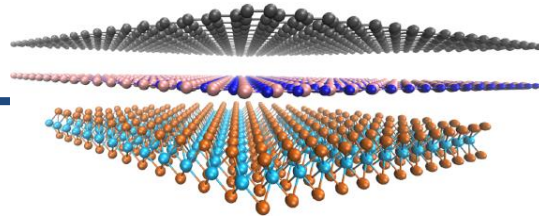
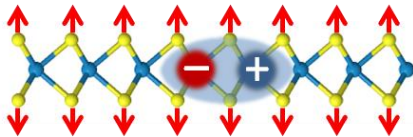


# 2D Materials: a unique toolkit for fundamental and applied physics

room  $T$  excitonic effects  
spin-valley locked properties

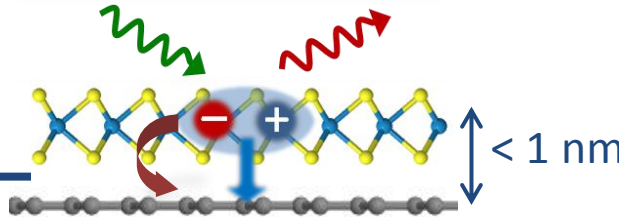


electron-phonon coupling

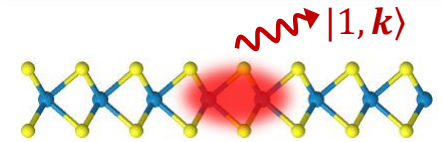


Gr  
BN  
TMD

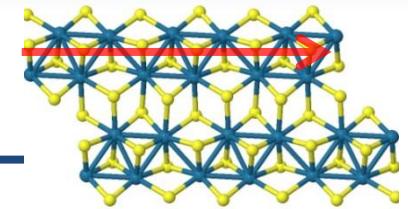
interlayer charge  
and exciton transport



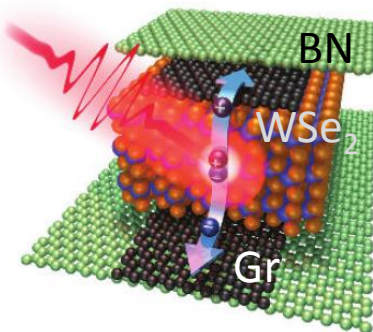
Nanophotonics,  
single photon emission



materials engineering  
(phase, anisotropy, strain)

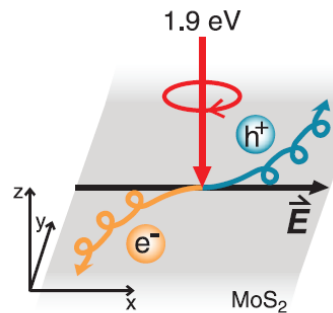


**optoelectronics**



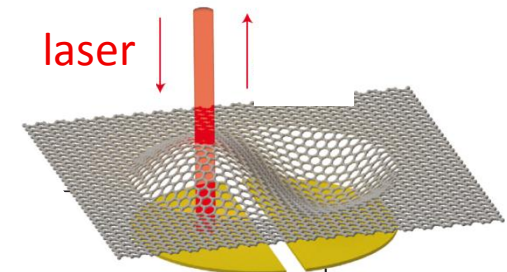
Massicotte *et al.*, Nat Nano 2016

**valleytronics**

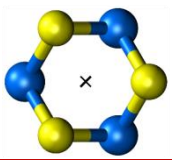


Mak *et al.*, Science 2014

**nanomechanics**

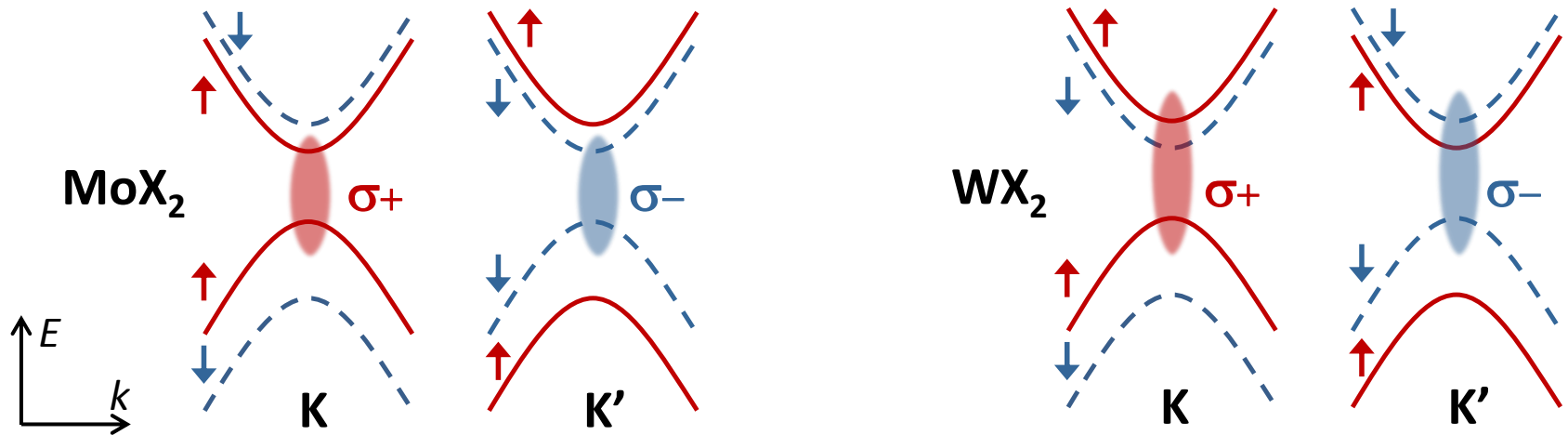


De Alba *et al.*, Nat. Nano 2016

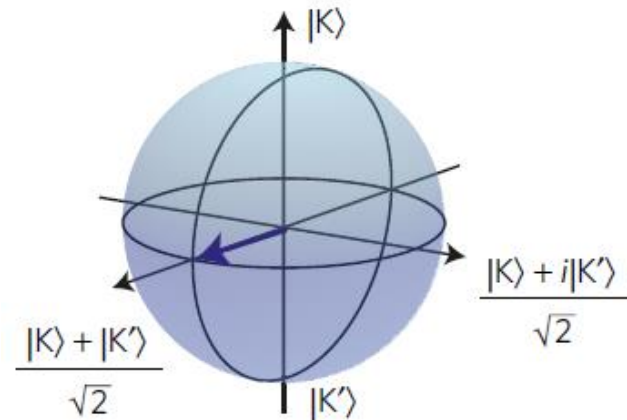
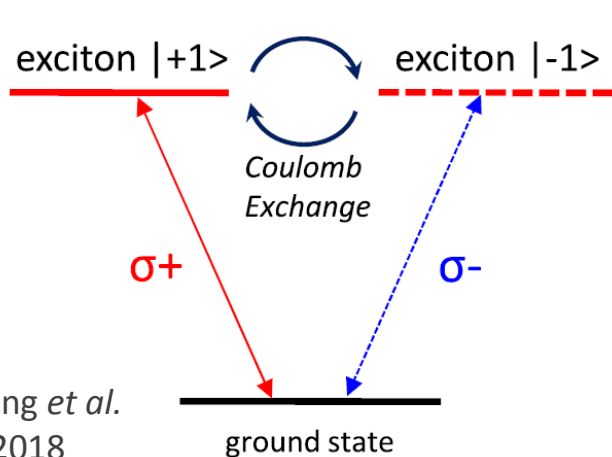


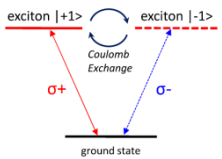
# Spin-valley locking in monolayer TMDs

*Broken inversion symmetry + strong spin orbit coupling*

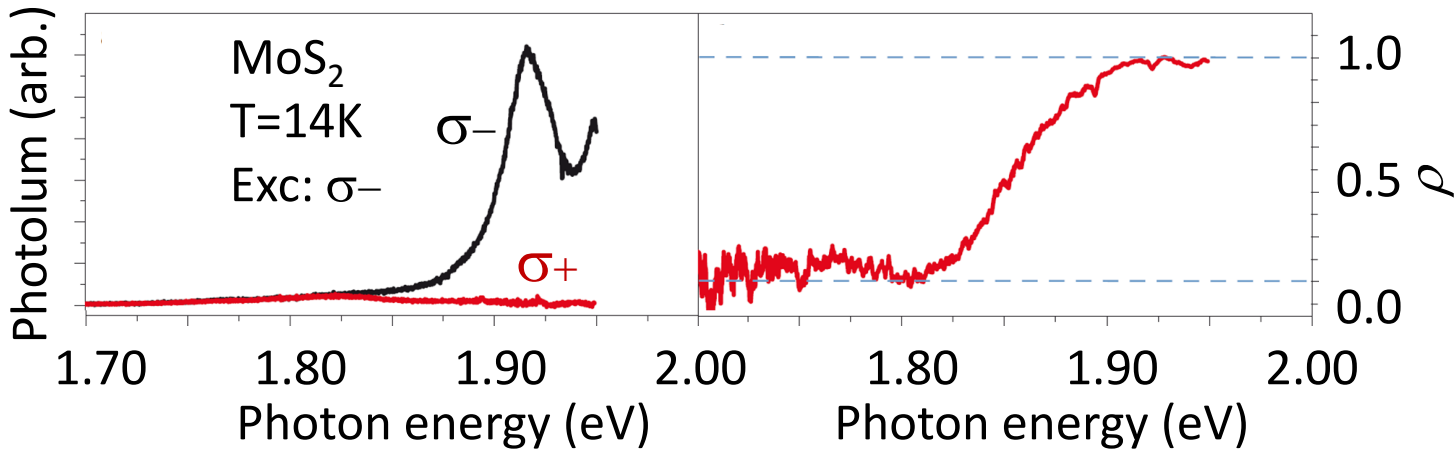


*Valley-polarized excitons...and their coherent superpositions*

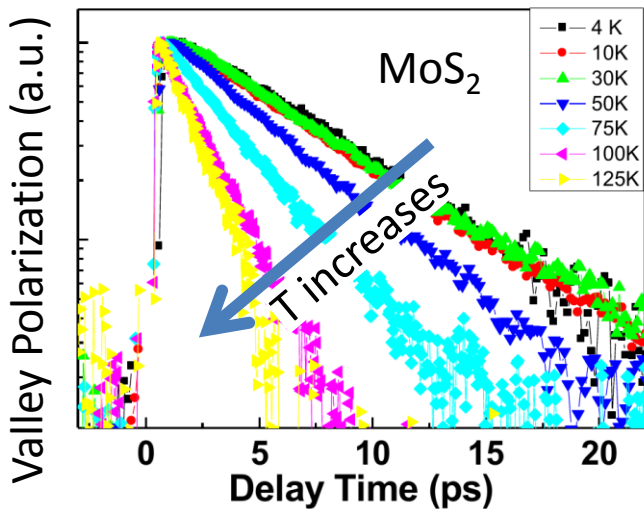




# Fragile Valley Contrasts



K.F. Mak *et al.*,  
Nat. Nano 2012



C. R. Zhu *et al.*, PRB 2014

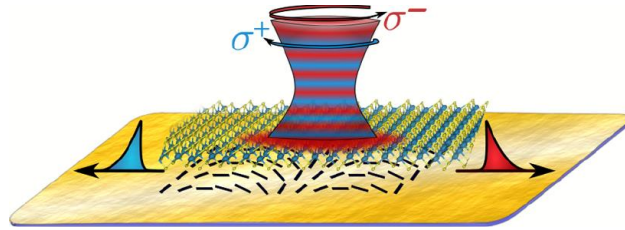
$\rho$  ( $\gamma$ ) degrees of circular (linear) polarization

- $\rho$  up to ~100 % at low T (MoS<sub>2</sub>)
- $\gamma$  up to 60 % at low T (MoS<sub>2</sub>)

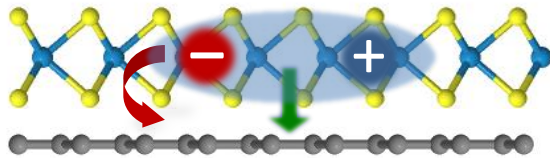
$$\rho = \frac{\rho_0}{1 + 2\tau_X/\tau_S}$$

- Valley contrasts are lost at room T
- How to protect/tailor valley contrasts?

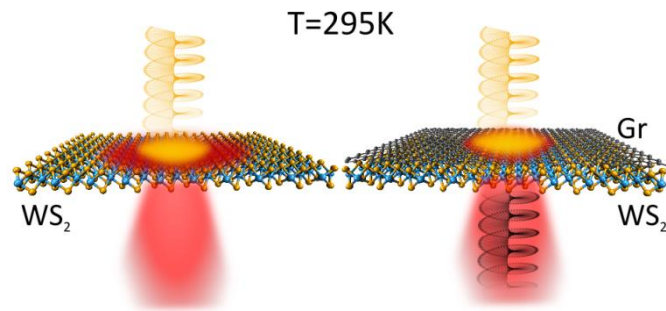
# Outline



*Room temperature Chiral coupling of valley excitons with spin-momentum locked surface plasmons*



*Graphene/TMD heterostructures as a 2D optoelectronic building block*

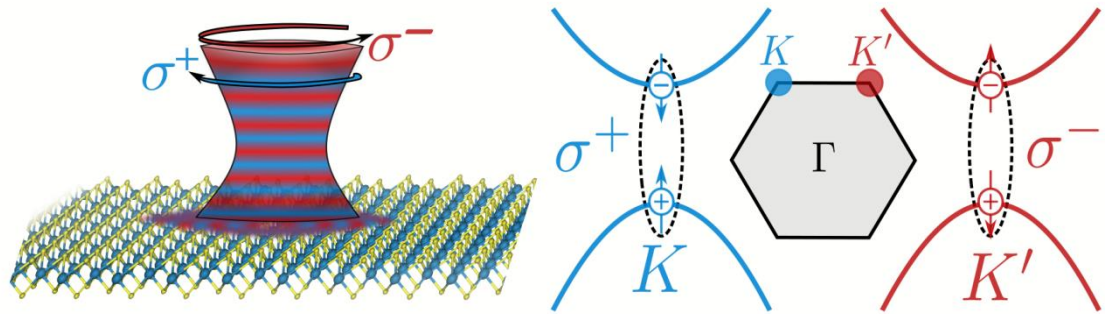
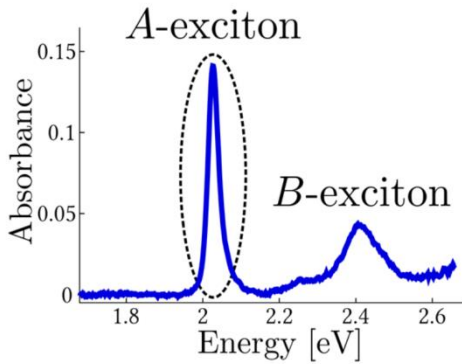


*Room temperature valley polarization and coherence in TMD/Graphene heterostructures*



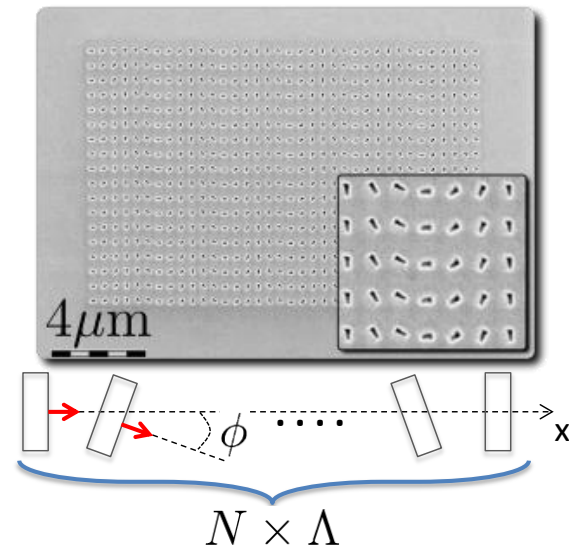
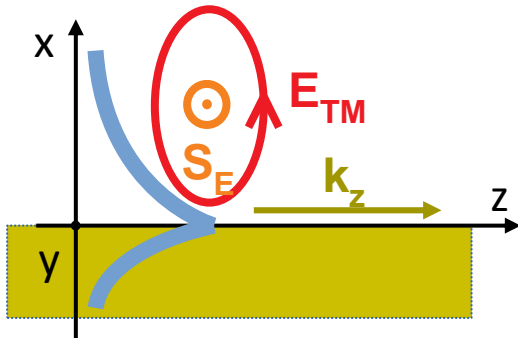
# 2D Matter meets 2D Light

## Semiconducting 2H-TMDs



*Helicity-dependent valley addressability*

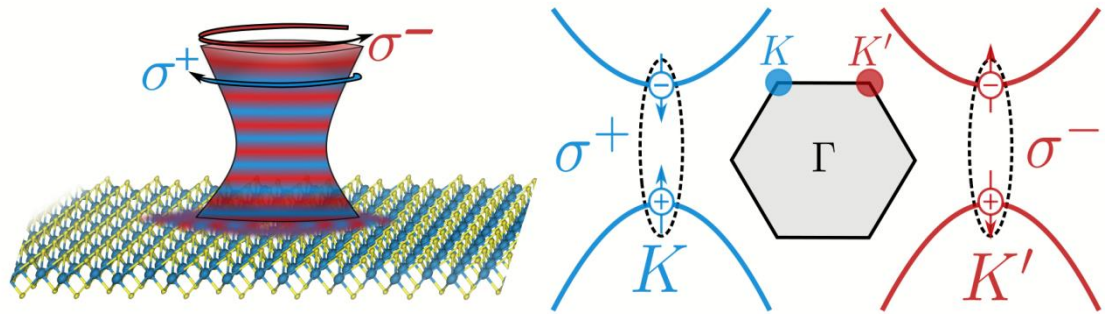
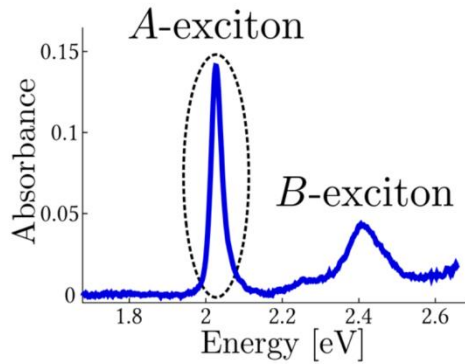
## Surface plasmons (SPs)



*Helicity-dependent directional SP launching*

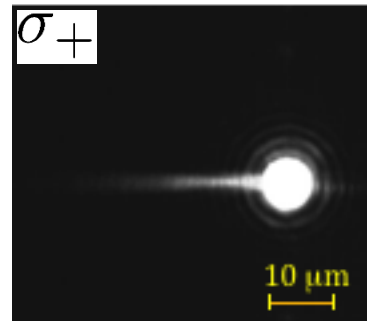
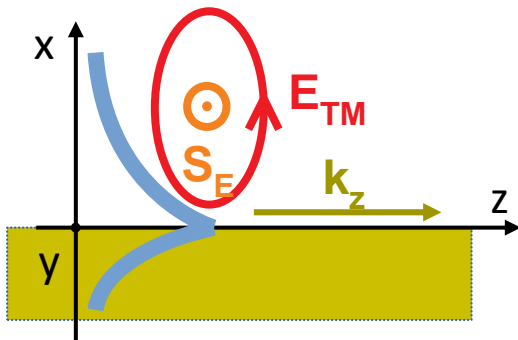
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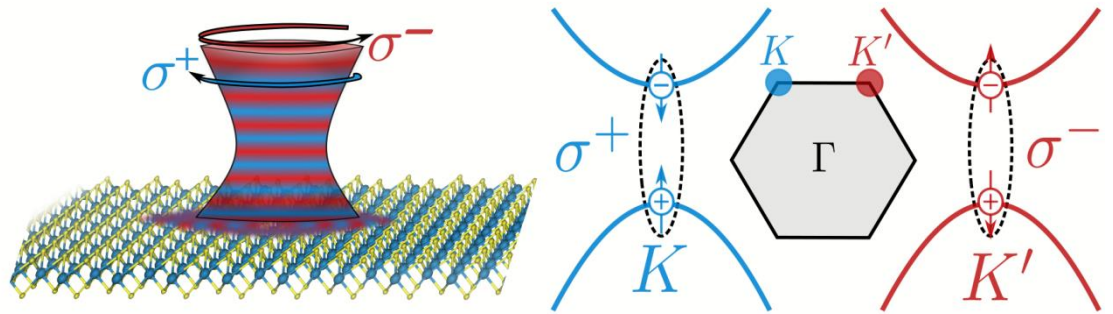
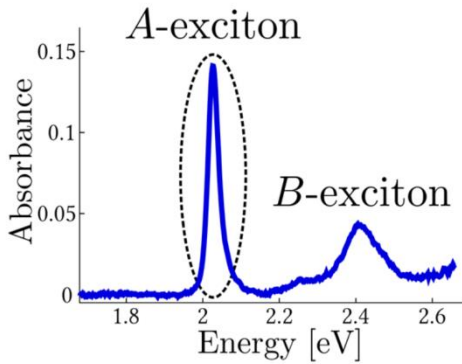
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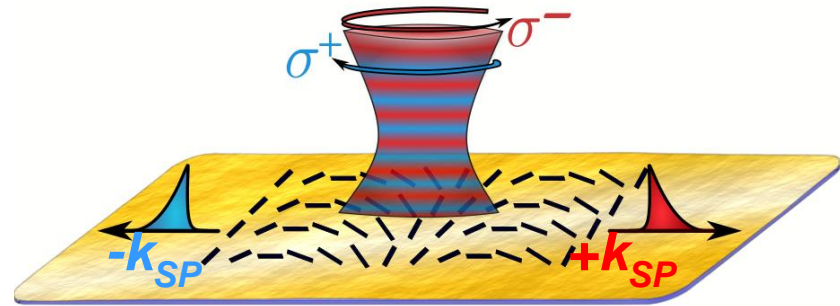
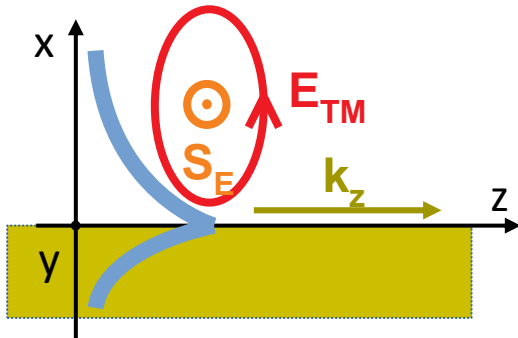
# 2D Matter meets 2D Light

## Semiconducting 2H-TMDs



*Helicity-dependent valley addressability*

## Surface plasmons (SPs)

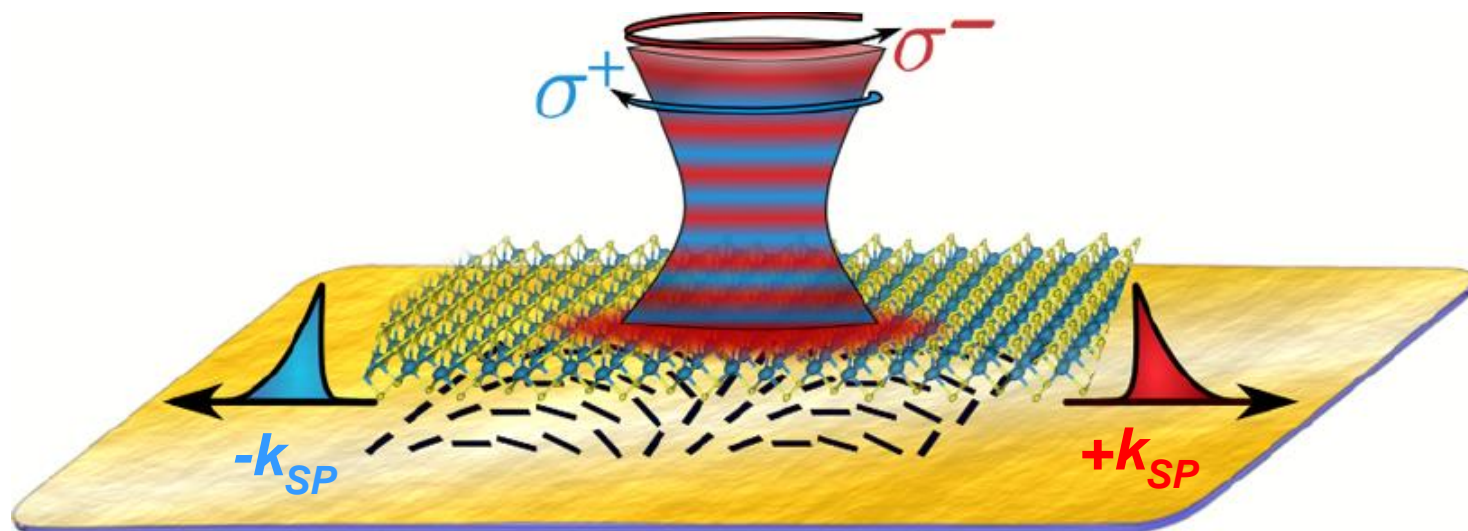


*Helicity-dependent directional SP launching*

*Tailored control of the valley pseudospin using TMD-SP architectures*

# 2D Matter meets 2D Light

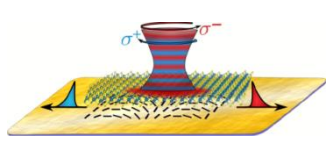
Room temperature **chiral coupling** between valley excitons and helicity-momentum locked surface plasmons



T. Chervy\*, S. Azzini\*, *et al.*, **ACS Photonics** 5, 1281 2018 (Arxiv 1701.07972)

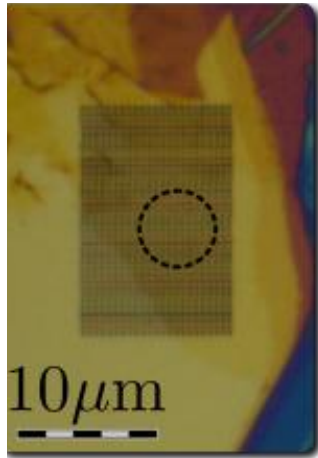
See also K. Kuipers' "intermezzo"

Coll: **T. Chervy**, **S. Azzini**, J.A. Hutchinson, T.W. Ebbesen, **C. Genet** (ISIS, Uni. Strasbourg)  
Y. Gorodetzki (Ariel, IL), S. Wang (Eindhoven, NL)

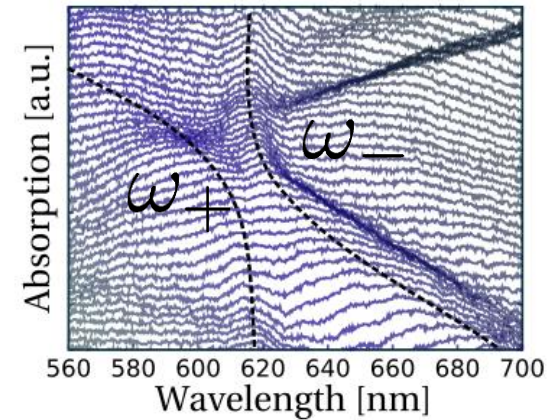


# Chiral coupling: 1L-TMD exciton with spin-orbit SP mode

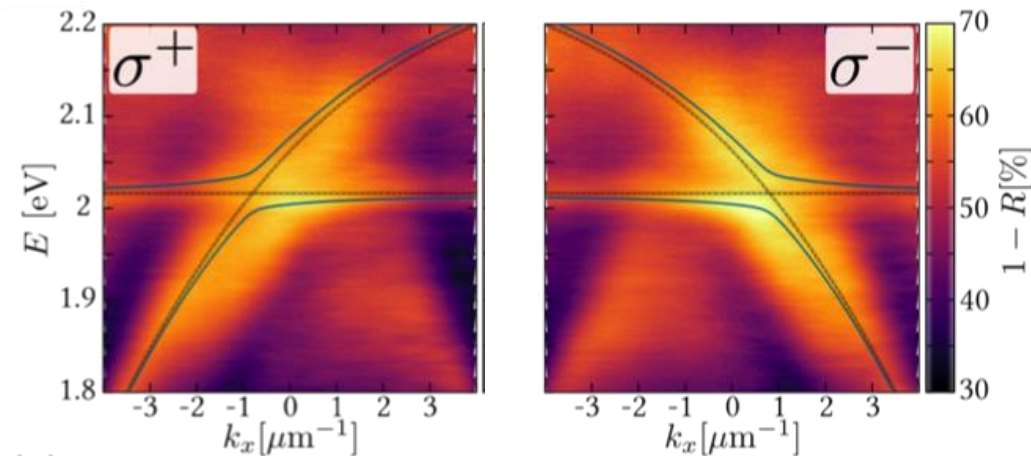
- ✓ Resonant condition TMD excitons / ( $n = \pm 1$ ,  $\sigma = \mp 1$ ) SP modes



Grating period  $\Lambda = 480$  nm  
 $\omega_{SP} \sim \omega_{Aexc} \sim 2.010$  eV



- ✓ Angle-resolved WL absorption ( $1-R \sim A$ ) – CPL analysis

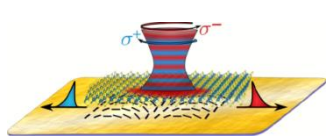


*Anticrossing*  $\hbar(\omega_+ - \omega_-) = 40$  meV

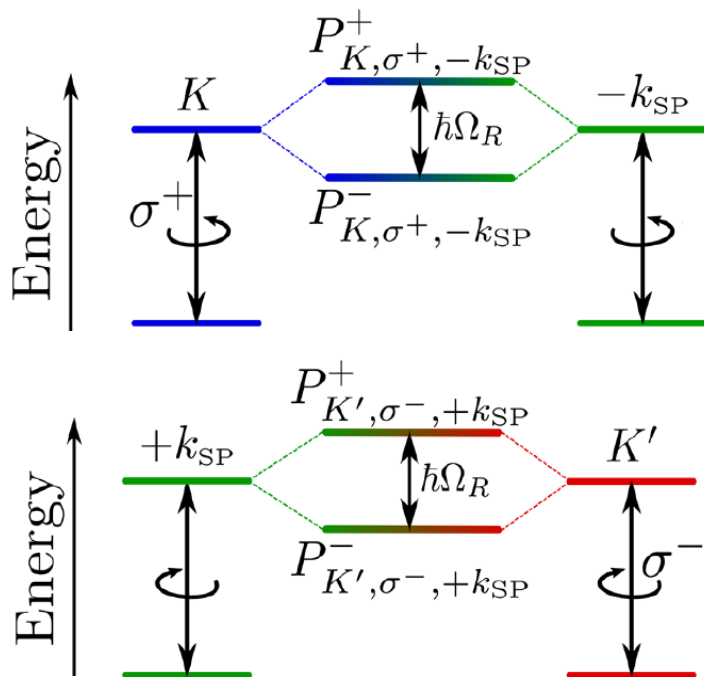
Strong-coupling FOM

$$\mathcal{C} = \frac{2\Omega_R}{\gamma_{exc} + \Gamma_{OSO}} = 0.9$$

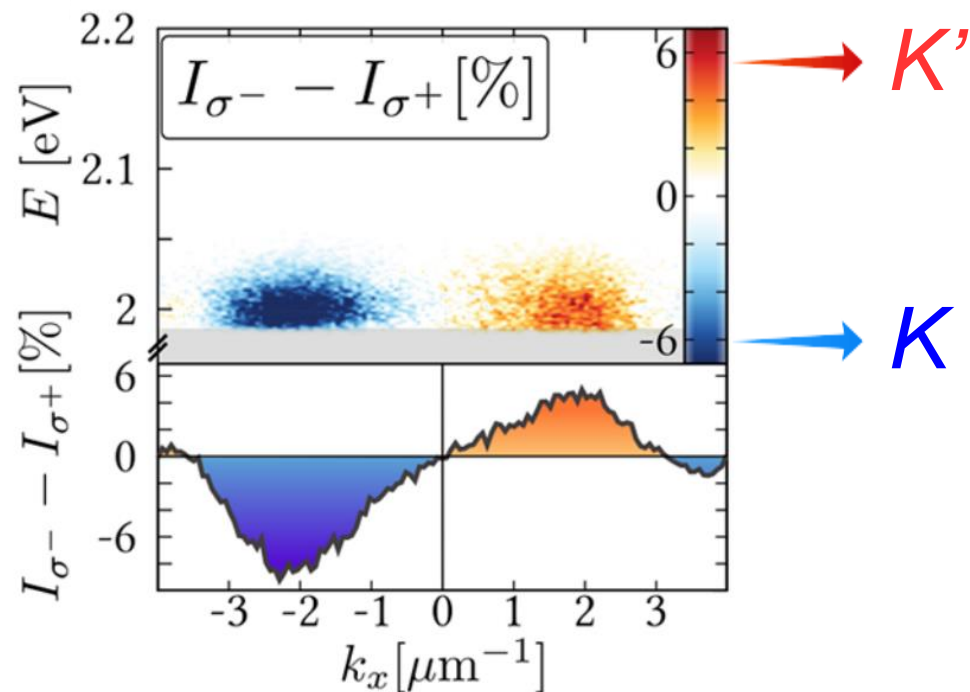




# Room temperature chiralitons



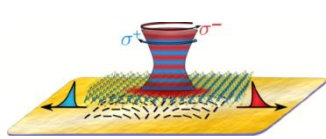
“Chiralitons”



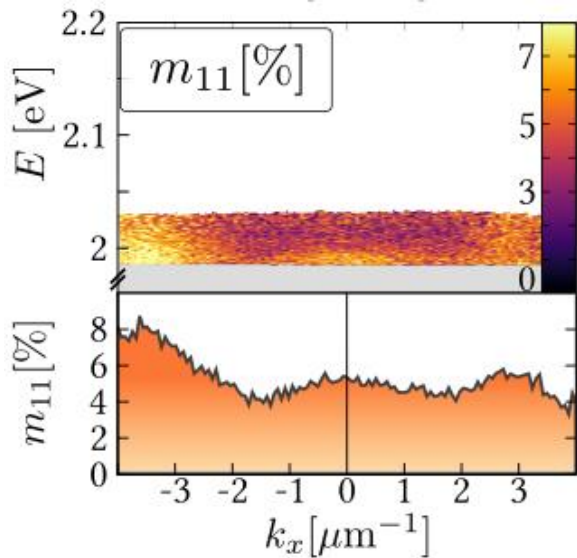
T. Chervy\*, S. Azzini\* *et al.*, ACS Photonics 2018

- Plasmon sorter efficiency: 15%
- Net chiraliton flow: 6 % → 40 %

**Recent related results:** Spin-momentum locking: TU Delft (Science 2018), UT Austin (arXiv:1801.06543)  
Valley polaritons: U. Sheffield, Nat. Photon. 2018, Northwestern U. Nat Photon 2018, Würzburg PRB2017



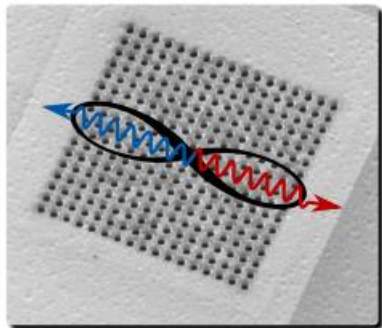
# Coherent superposition of counterpropagating chiralitons



- *PL polarization tomography on a linear basis*  
*Measured as the  $m_{11}$  Mueller matrix element*

- *Chiralitonic valley coherence*

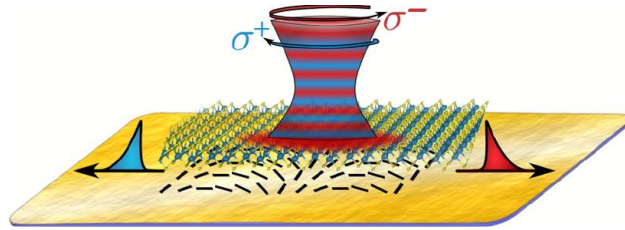
$$(S_1|^{TM} - S_1|^{TE})/2 = m_{11} \sim 5 - 8 \%$$



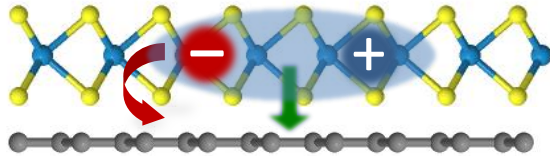
$$|\Psi\rangle = |P_{K,\sigma_+,-k_{SP}}^\pm\rangle + |P_{-K,\sigma_+,+k_{SP}}^\pm\rangle$$

Outlook: No valley contrasts in bare TMD → Cavity protection mechanism?  
Designing new 2D building blocks for chiral optics.

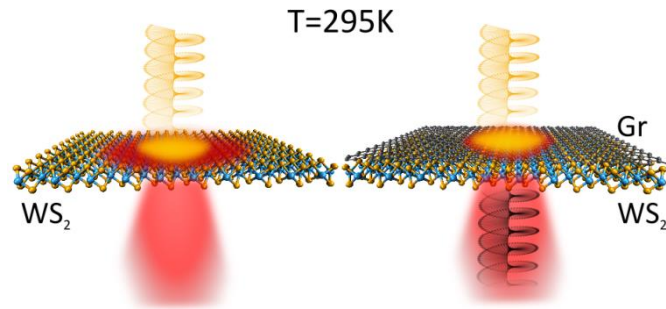
# Outline



*Room temperature Chiral coupling of valley excitons with spin-momentum locked surface plasmons*



*Graphene/TMD heterostructures as a 2D optoelectronic building block*



*Room temperature valley polarization and coherence in TMD/Graphene heterostructures*

# Gr/TMD heterostructures: why the interest?

- **Graphene: 2D semi-metallic channel**

- ✓ Quasi-transparent ( $\sim 2\%$  absorption per layer)
- ✓ High carrier mobility and large carrier density
- ✓ Gate-tunable properties

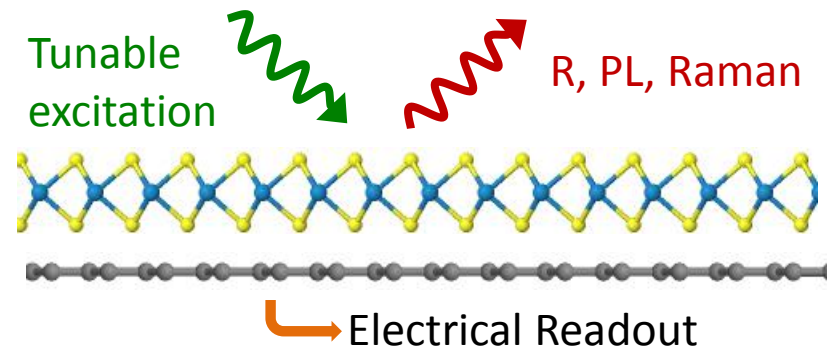
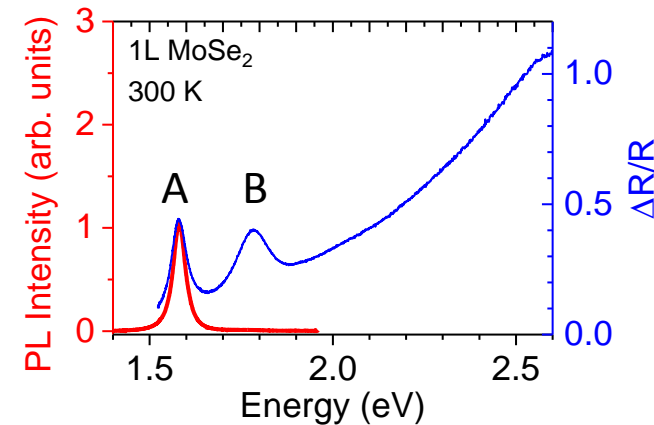
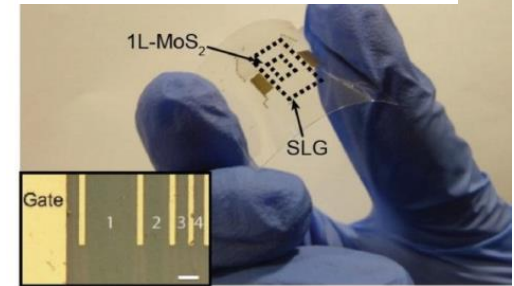
- **TMD: 2D semiconducting channel**

- ✓ Strong light-matter interaction
- ✓ Broadband absorption and tunable emission

- **Gr-TMD heterostructures:**

- ✓ Strong interlayer coupling  
(J. He *et al.*, Nat Comm. 2014)
- ✓ Photogating/photodetection  
(W. Zhang *et al.*, Sci. Rep. 2014)
- ✓ ps-range photoresponse  
(M. Massicotte *et al.*, Nat Nano 2016)

De Fazio *et al.*, ACS Nano 2016

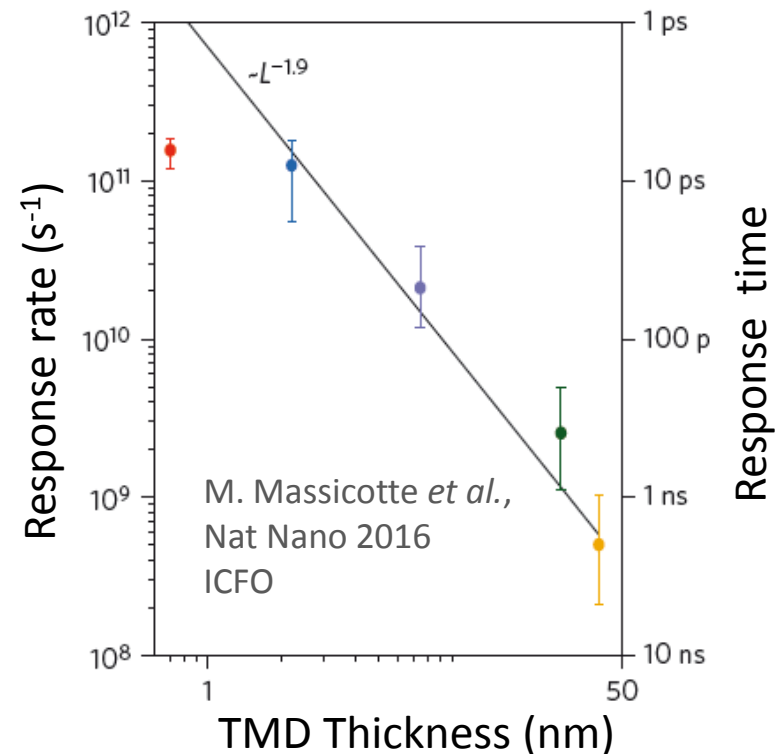
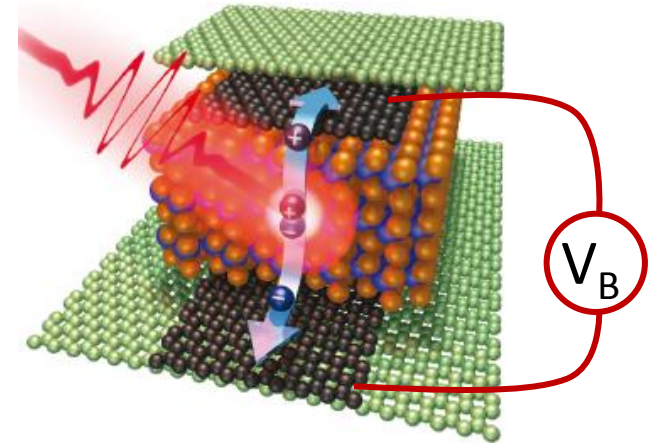


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- ✓ **ps-range photoresponse**  
(M. Massicotte et al., Nat Nano 2016)

*Low efficiency with monolayer TMD*

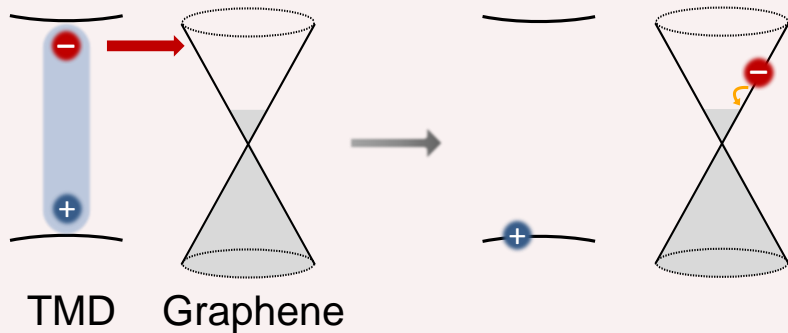
➤ *Energy transfer?*



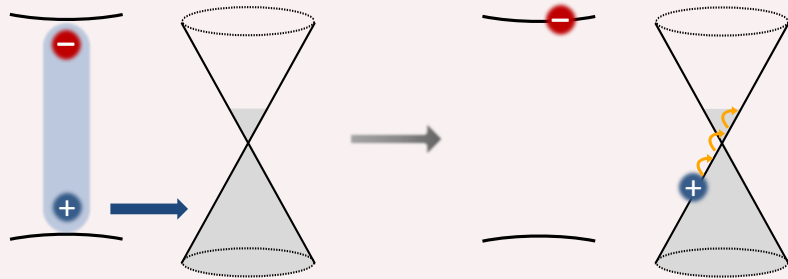


# Charge and energy transfer mechanisms

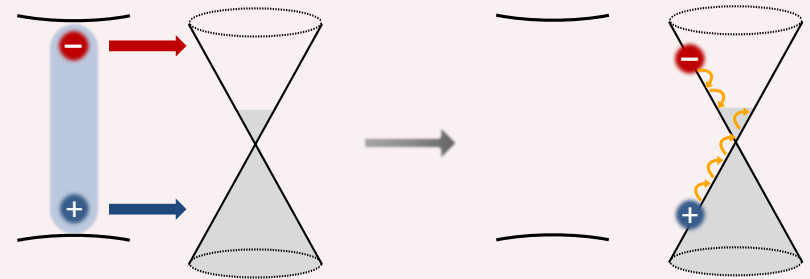
(a) Interlayer Electron Transfer



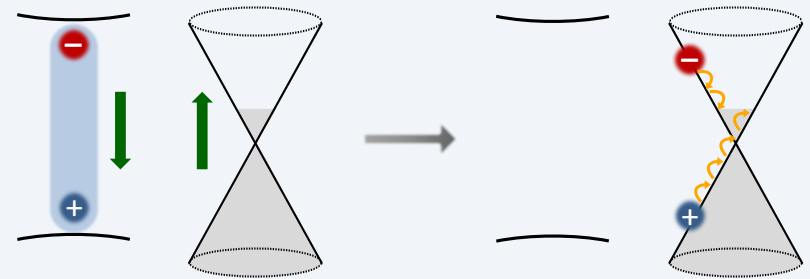
(b) Interlayer Hole Transfer



(c) Dexter-type Interlayer Energy Transfer



(d) Förster-type Interlayer Energy Transfer

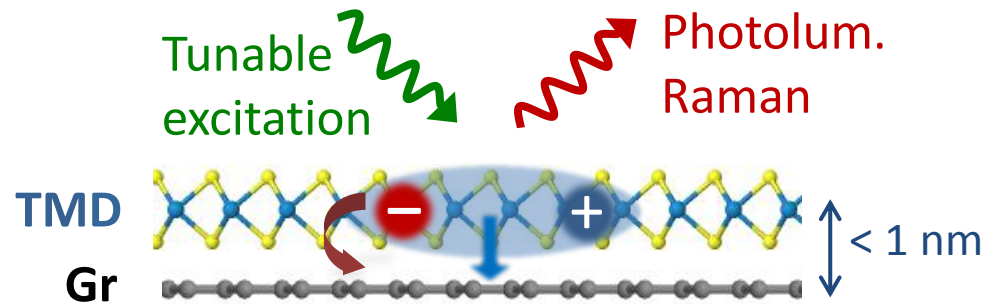
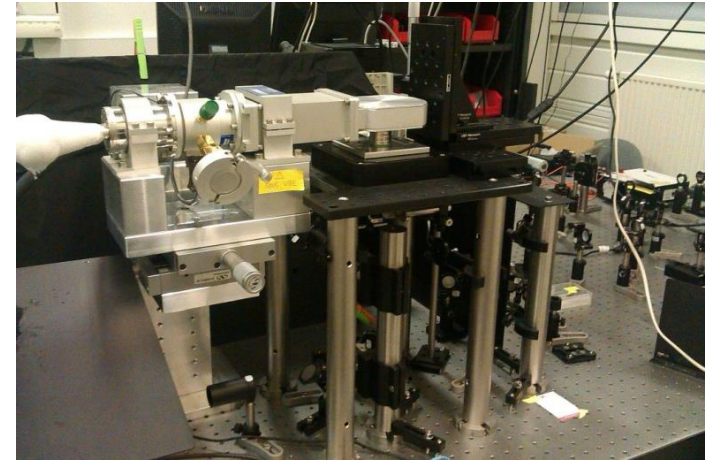
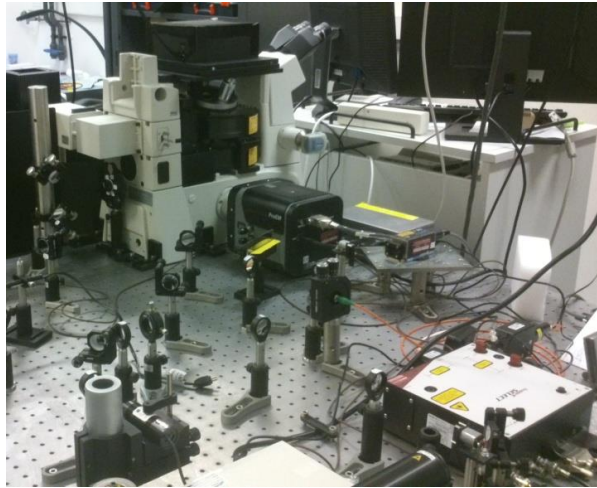


- ✓ Probed in the steady state (Raman)
- ✓ Balanced electron and hole transfer

- ✓ Determine exciton dynamics  
→ Relative efficiencies?

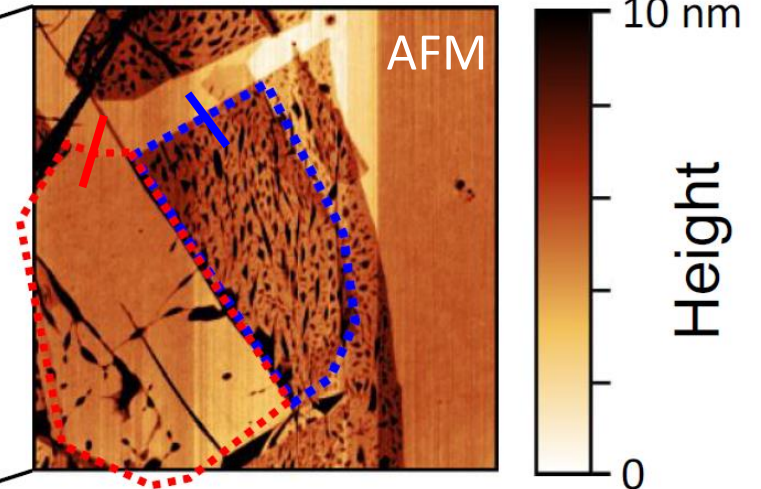
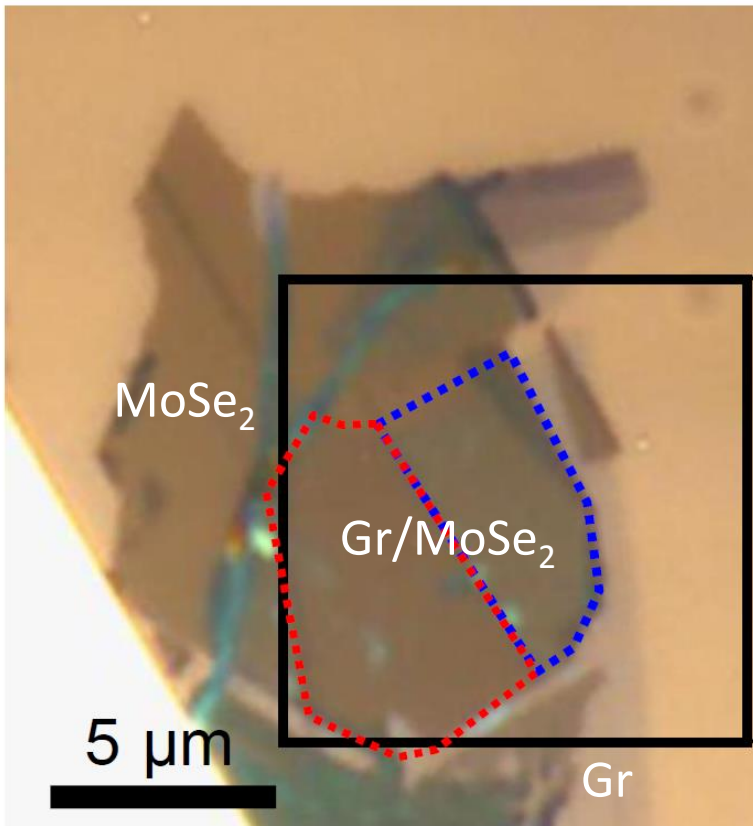
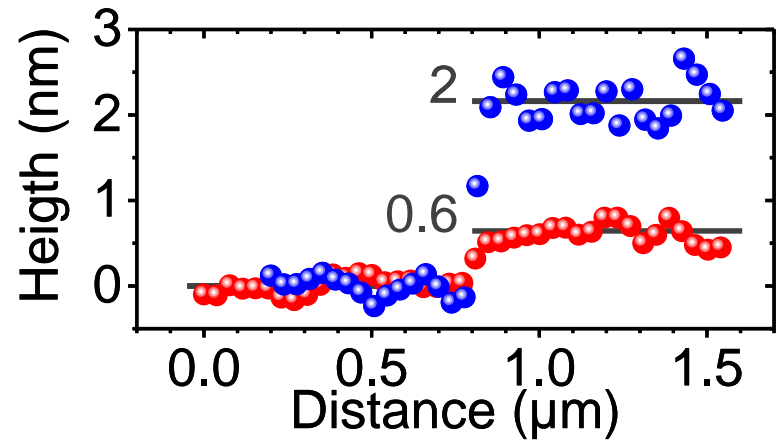


# Our Experimental Approach



- *Understanding near-field interactions (IET vs ICT)*
- *Implications for optoelectronic devices*

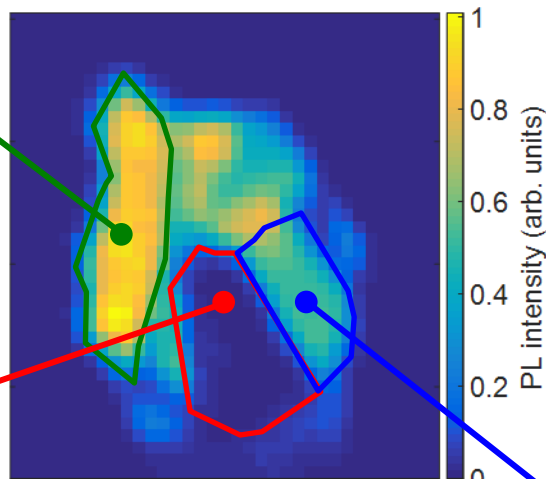
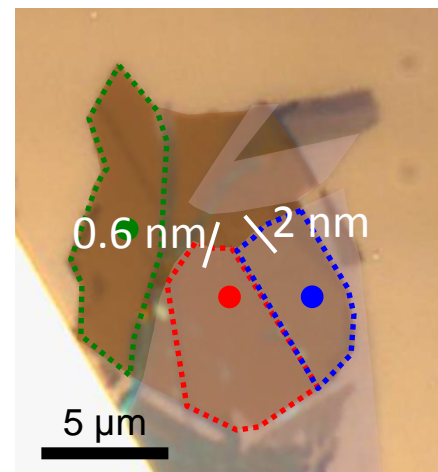
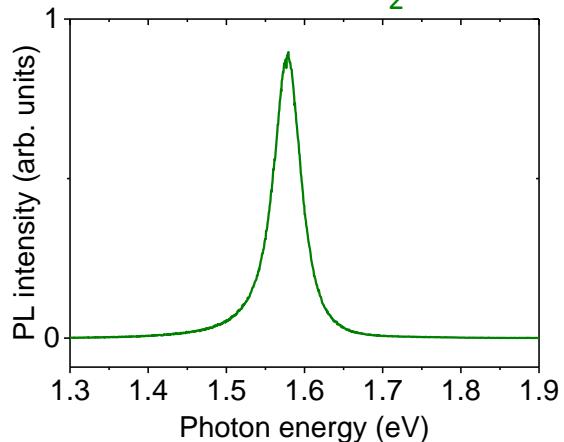
# Atomic Force Microscopy



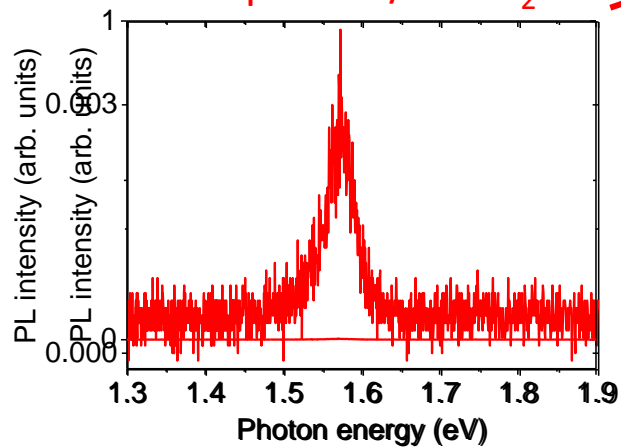
*Smooth Gr/MoSe<sub>2</sub> domains*

# Photoluminescence mapping

Bare MoSe<sub>2</sub>

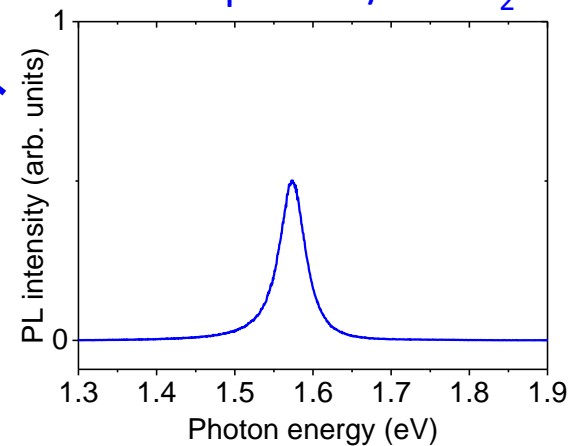


Coupled Gr/MoSe<sub>2</sub>

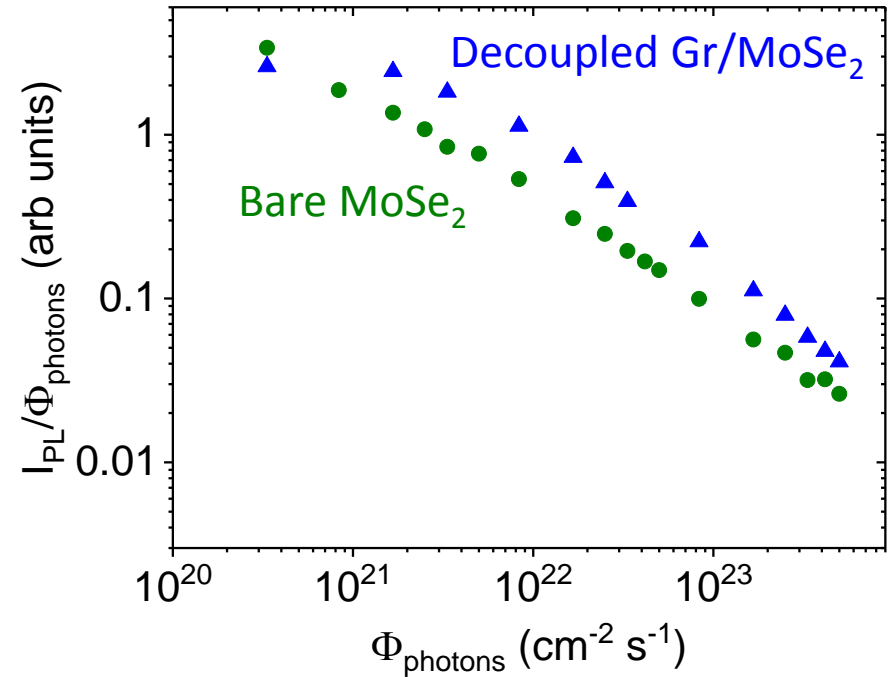
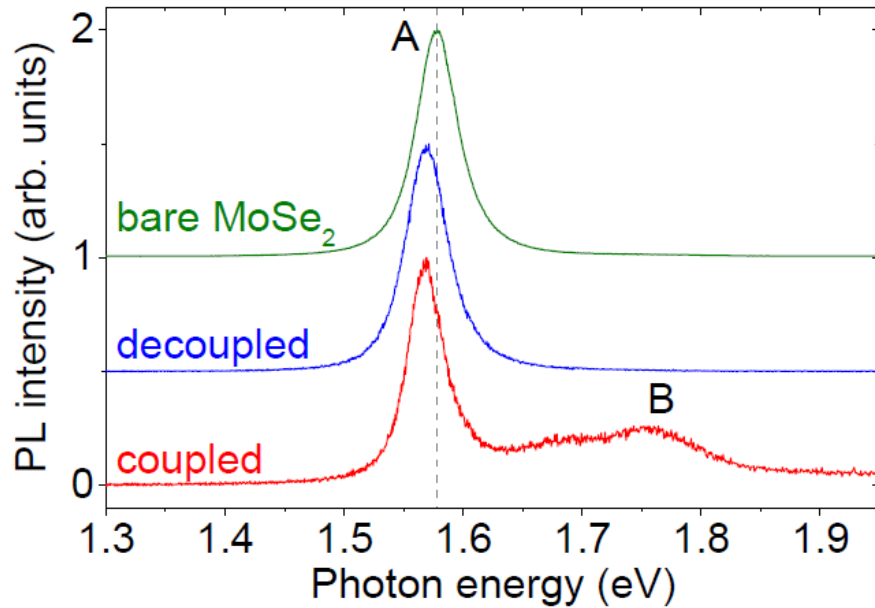


➔ Strong PL Quenching ~ 300

Decoupled Gr/MoSe<sub>2</sub>



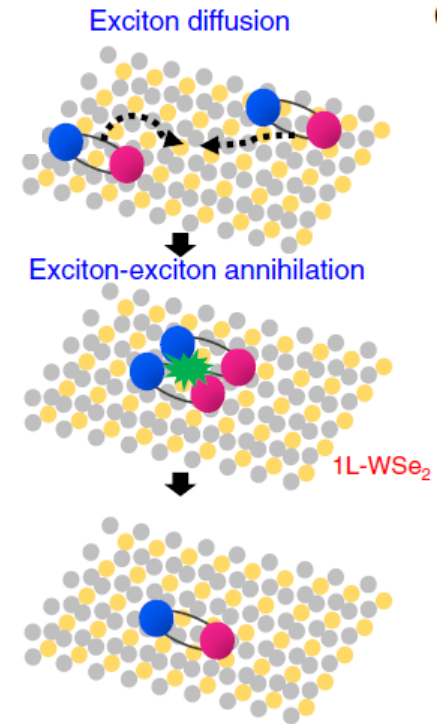
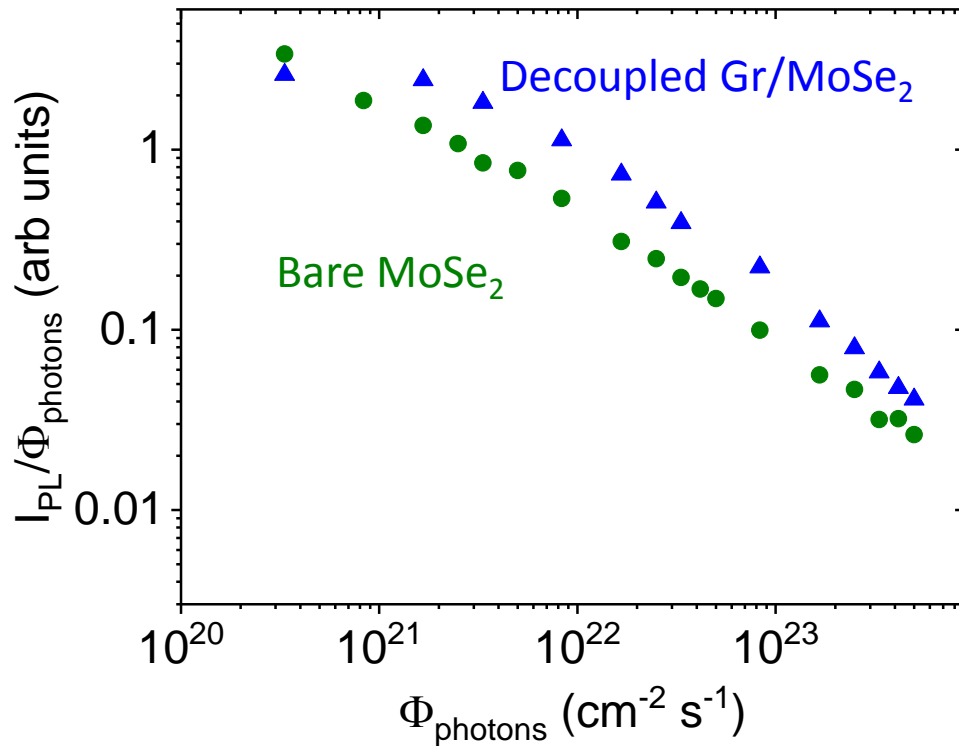
# Exciton: dynamics: PL vs $\Phi_{\text{photons}}$



- PL saturation on **bare** and **decoupled** MoSe<sub>2</sub>



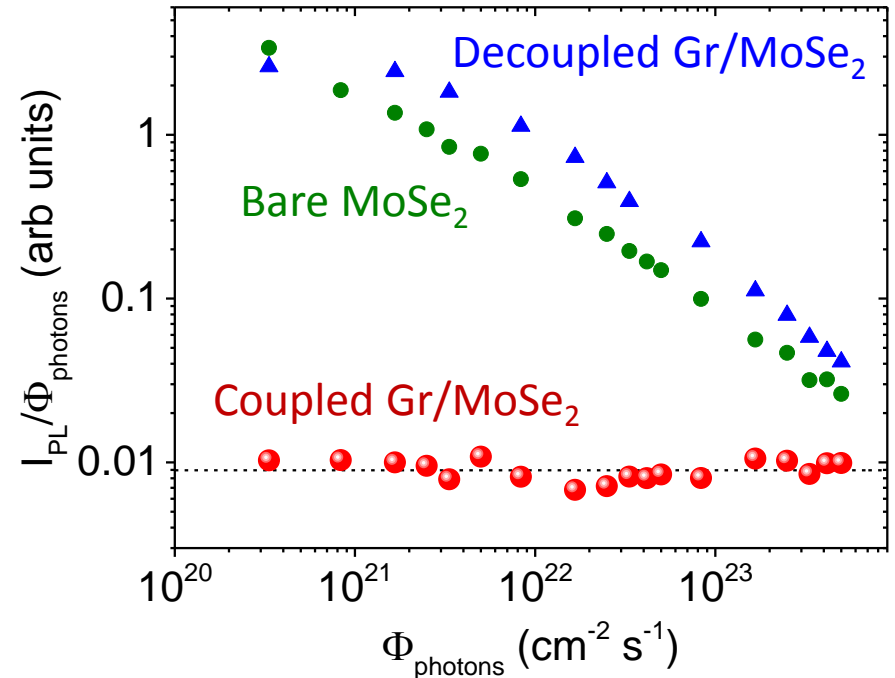
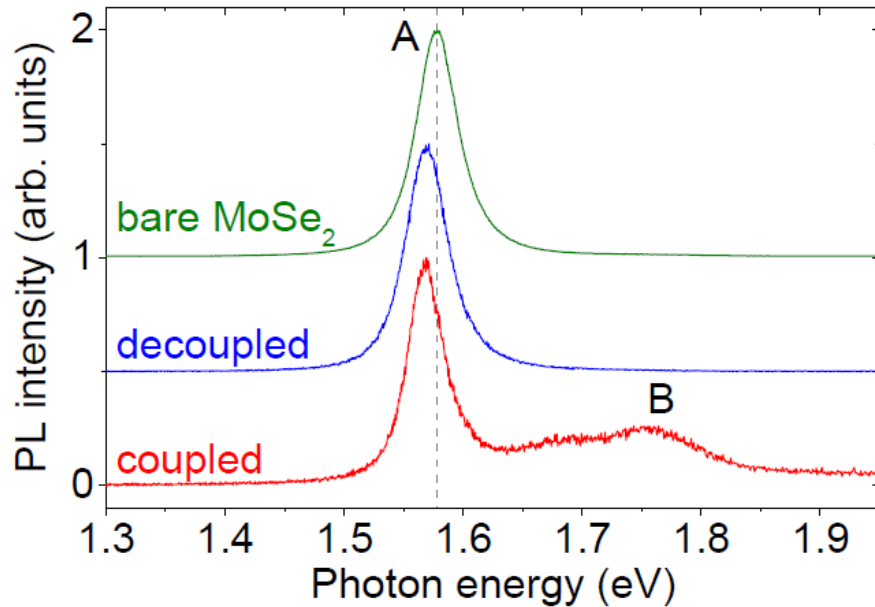
# Exciton dynamics: PL vs $\Phi_{\text{photons}}$



S. Mouri *et al.*, PRB 2014

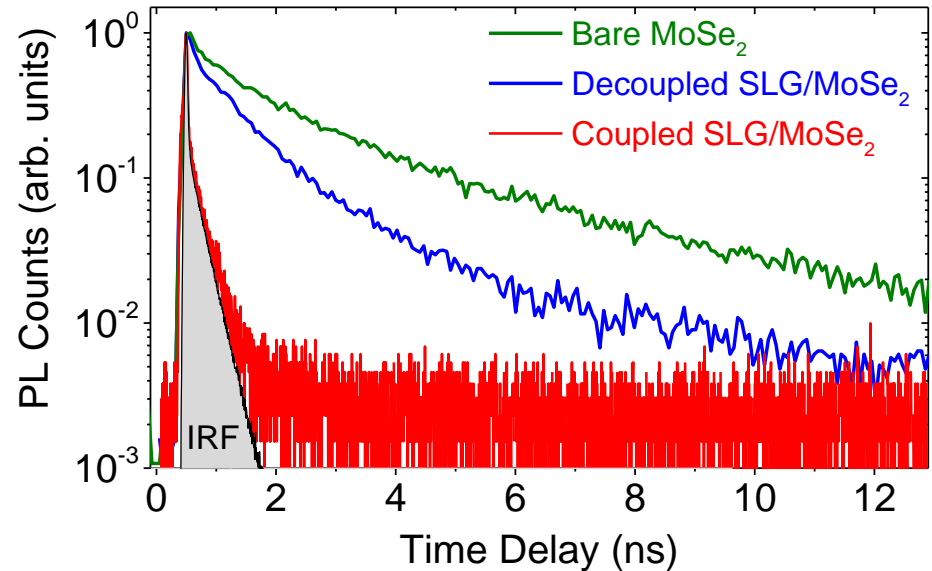
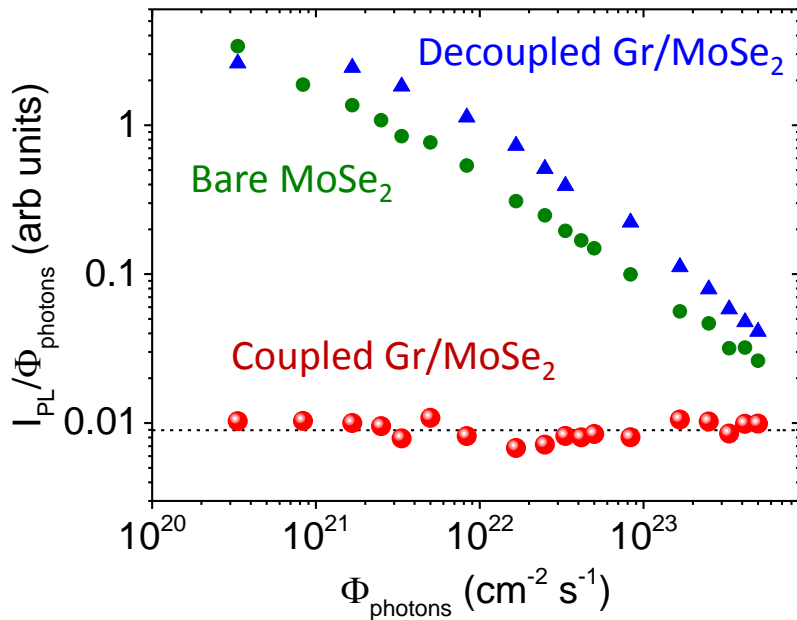
- PL saturation on **bare** and **decoupled** MoSe<sub>2</sub>:  
→ *Exciton-Exciton Annihilation (EEA)*

# Exciton dynamics: PL vs $\Phi_{\text{photons}}$



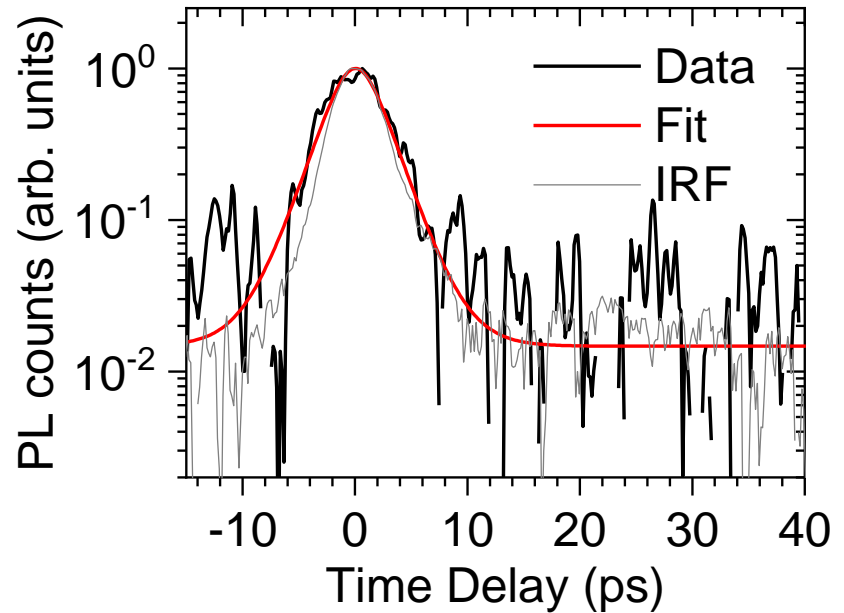
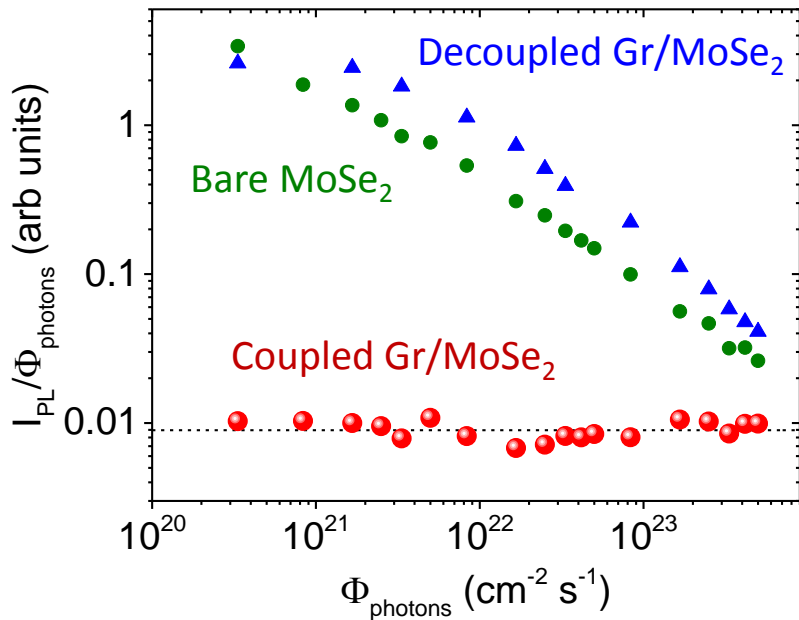
- PL saturation on **bare** and **decoupled** MoSe<sub>2</sub>  
→ *Exciton-Exciton Annihilation (EEA)*
- **No PL saturation on Gr/MoSe<sub>2</sub> and  $I_{\text{PL}}(\text{B}) \sim I_{\text{PL}}(\text{A})$**

# Exciton dynamics: PL vs $\Phi_{\text{photons}}$



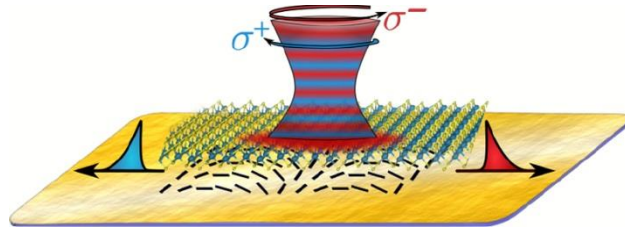
- PL saturation on **bare** and **decoupled** MoSe<sub>2</sub>
- **No PL saturation on Gr/MoSe<sub>2</sub> and  $I_{\text{PL}}(\text{B}) \sim I_{\text{PL}}(\text{A})$**   
→ Drastic reduction of the excitonic lifetime ( $< 1$  ps)  
→ **Fast interlayer Energy Transfer?**

# Exciton dynamics: PL vs $\Phi_{\text{photons}}$

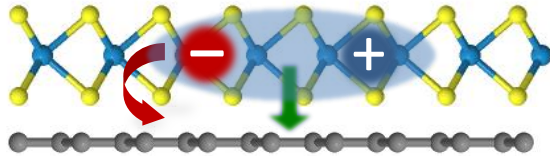


- PL saturation on **bare** and **decoupled** MoSe<sub>2</sub>
- **No PL saturation on Gr/MoSe<sub>2</sub> and  $I_{\text{PL}}(\text{B}) \sim I_{\text{PL}}(\text{A})$**   
→ Drastic reduction of the excitonic lifetime ( $< 1$  ps)  
→ **Fast interlayer Energy Transfer?**

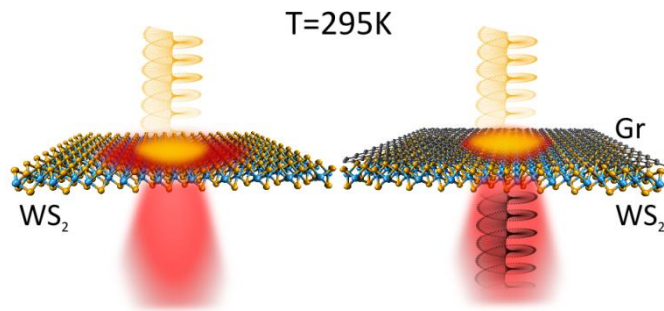
# Outline



*Room temperature Chiral coupling of valley excitons with spin-momentum locked surface plasmons*



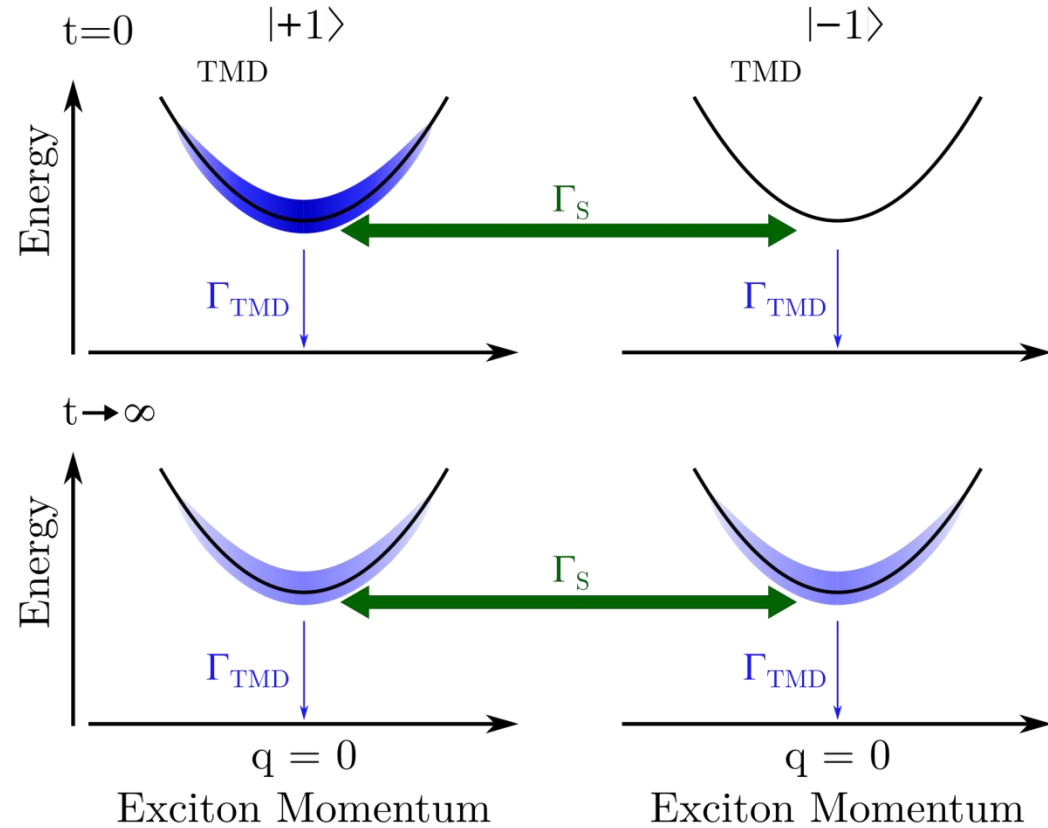
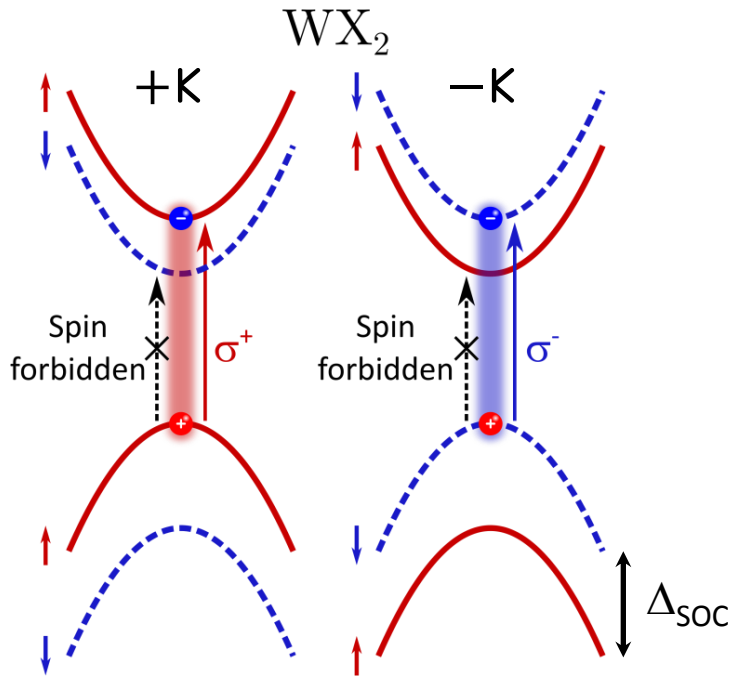
*Graphene/TMD heterostructures as a 2D optoelectronic building block*



*Room temperature valley polarization and coherence in TMD/Graphene heterostructures*



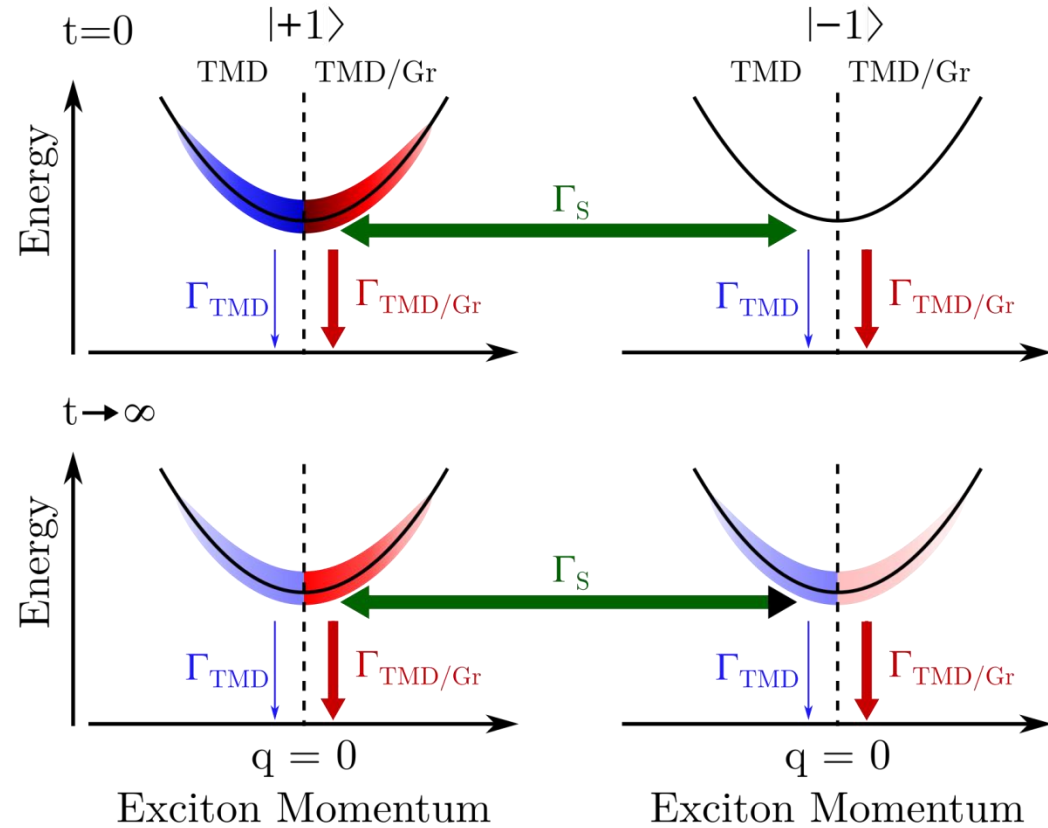
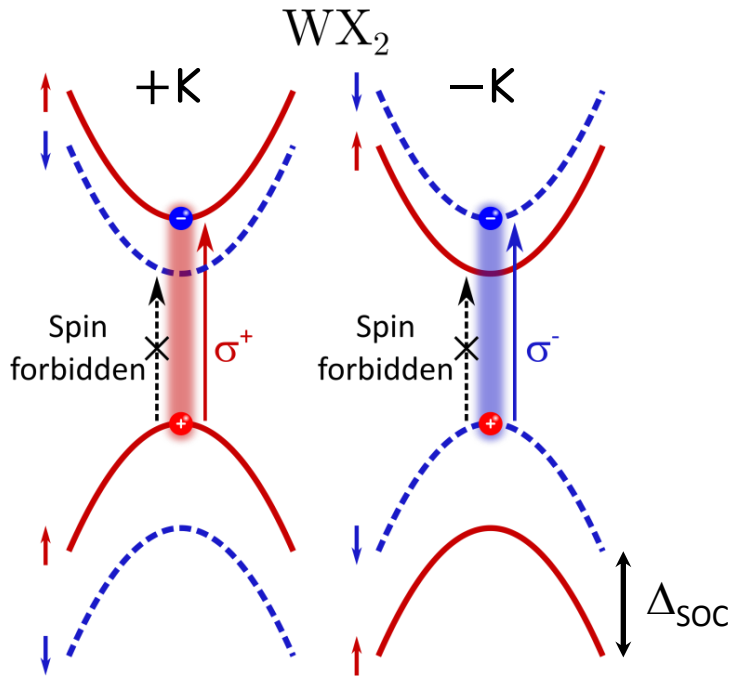
# Back to valley contrasts



Photonic state	Excitonic state
$ \sigma^\pm\rangle$	$ \pm 1\rangle$
$\frac{1}{\sqrt{2}}( \sigma^+\rangle \pm  \sigma^-\rangle)$	$\frac{1}{\sqrt{2}}( +1\rangle \pm  -1\rangle)$

➤  $\Gamma_{\text{TMD}} \ll \Gamma_S \Rightarrow 0\%$  valley polarization

# Back to valley contrasts

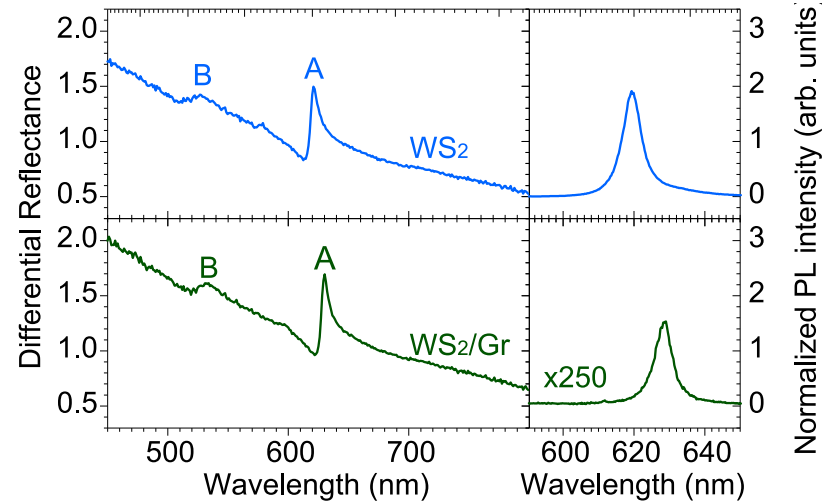
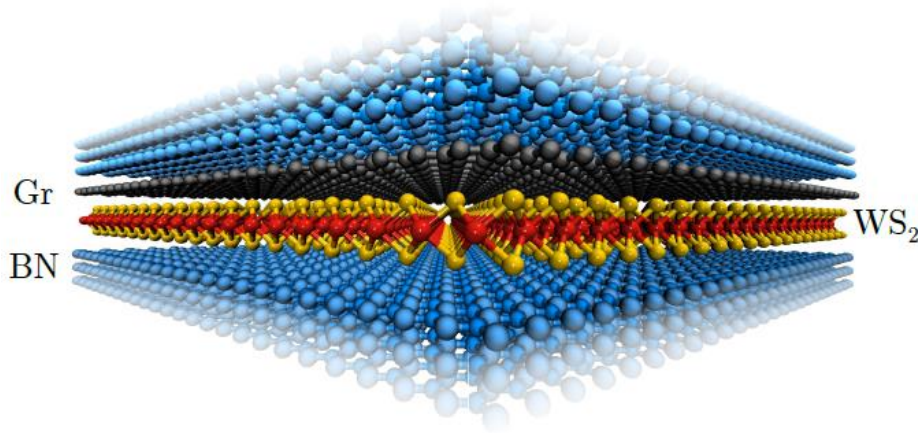


Photonic state	Excitonic state
$ \sigma^\pm\rangle$	$ \pm 1\rangle$
$\frac{1}{\sqrt{2}}( \sigma^+\rangle \pm  \sigma^-\rangle)$	$\frac{1}{\sqrt{2}}( +1\rangle \pm  -1\rangle)$

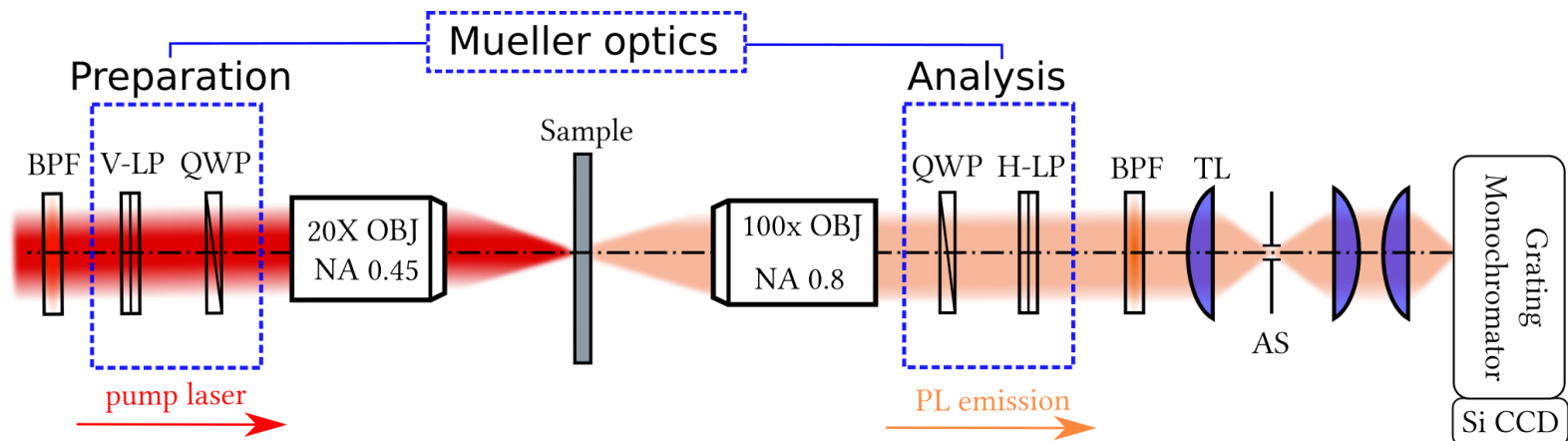
- $\Gamma_{TMD} \ll \Gamma_S \Rightarrow 0\%$  valley polarization
- $\Gamma_{TMD/Gr} \ll \Gamma_S \Rightarrow$  finite valley polarization

# Our experimental approach

## BN-encapsulated $WS_2$ -Gr heterostructure



## Mueller polarimetry setup



# Mueller Polarimetry

$$\mathbf{S}^{\text{out}} = \begin{pmatrix} I \\ I_V - I_H \\ I_{45} - I_{-45} \\ I_{\sigma^+} - I_{\sigma^-} \end{pmatrix}_{\text{out}} = \mathcal{M} \cdot \mathbf{S}^{\text{in}} = \mathcal{M} \begin{pmatrix} I_0 \\ I_V - I_H \\ I_{45} - I_{-45} \\ I_{\sigma^+} - I_{\sigma^-} \end{pmatrix}_{\text{in}}$$

$$\mathcal{M} = \begin{pmatrix} m_{00} & m_{01} & m_{02} & m_{03} \\ m_{10} & m_{11} & m_{12} & m_{13} \\ m_{20} & m_{21} & m_{22} & m_{23} \\ m_{30} & m_{31} & m_{32} & m_{33} \end{pmatrix}$$

$m_{i0}$ : birefringence

$m_{0i}$ : dichroism

$m_{11,22}$  = valley coherence

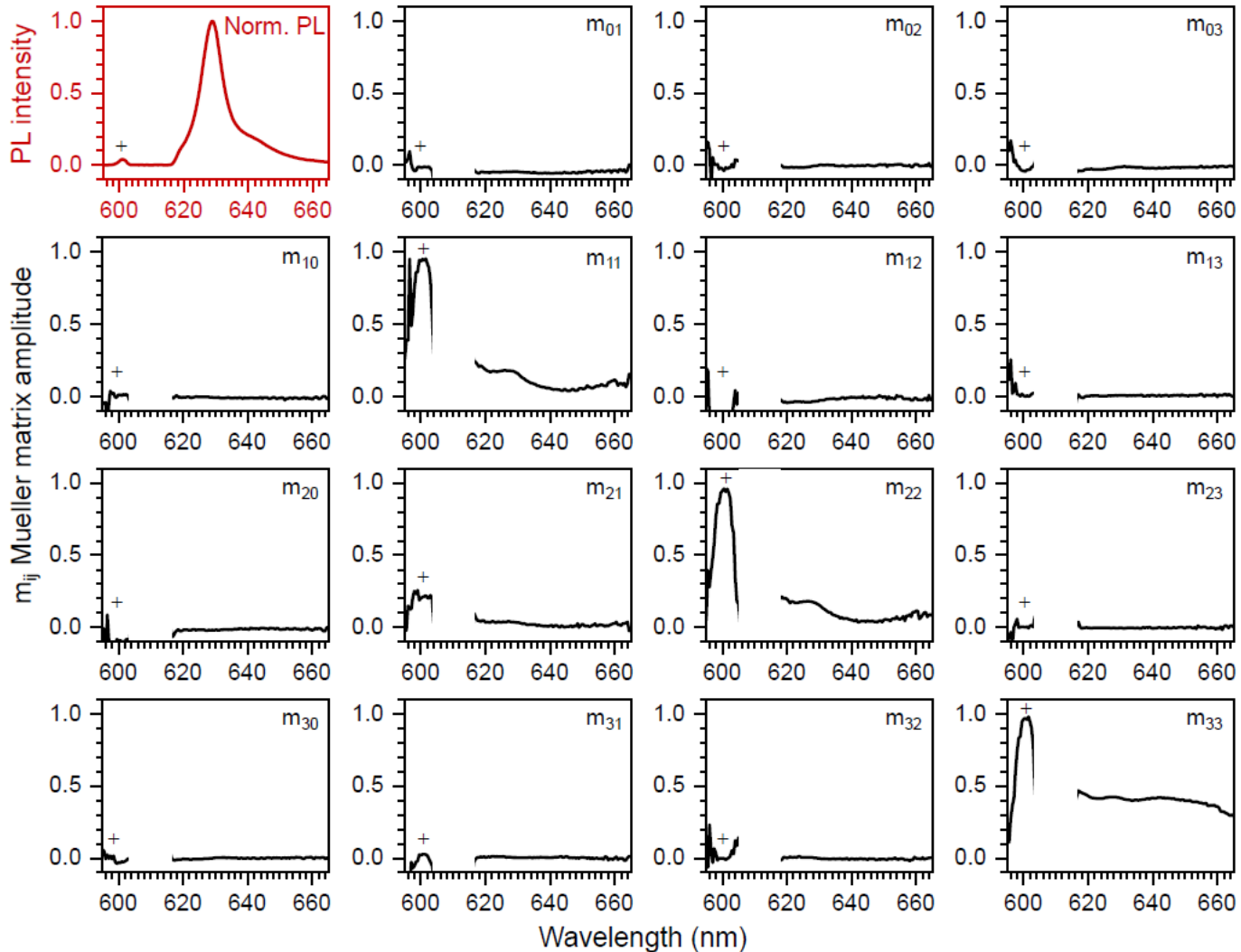
$m_{33}$  = valley polarization

*Degrees of linear and circular polarization*

$$\gamma^{VH} = \frac{m_{10} + m_{11}}{m_{00} + m_{01}}, \gamma^{+45^\circ, -45^\circ} = \frac{m_{20} + m_{22}}{m_{00} + m_{02}}, \rho^\pm = \frac{m_{30} \pm m_{33}}{m_{00} \pm m_{03}}$$

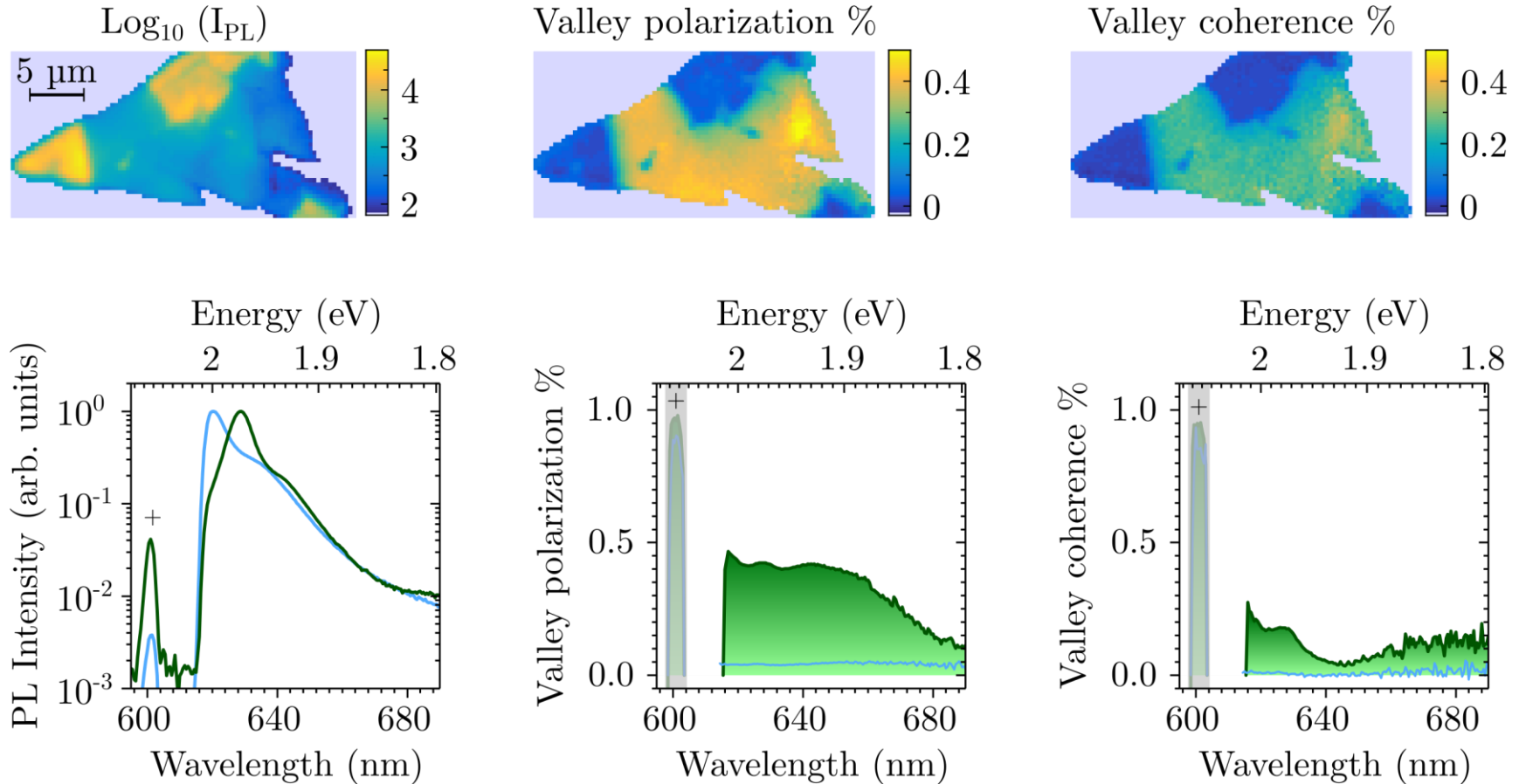
# Mueller Polarimetry in $WS_2/Gr$

Laser  
@600 nm



Experimental “sanity check” :  $m_{11} = m_{22}$  and  $m_{ij, i \neq j} = 0$

# Mapping valley contrasts



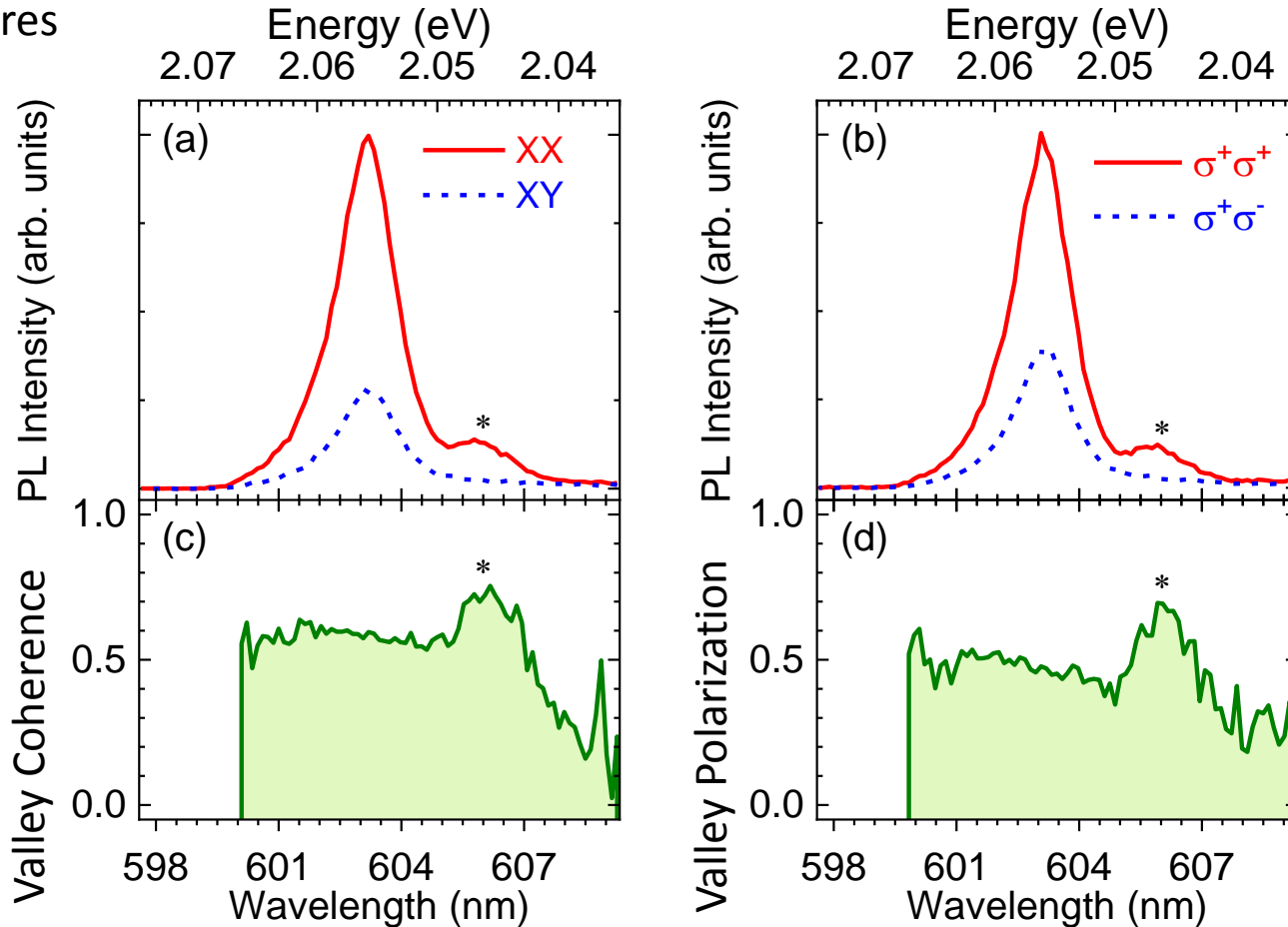
E.Lorchat, S.Azzini, T.Chervy *et al.*, ArXiv:1804.06725 (doi: [10.1021/acsp Photonics.8b01306](https://doi.org/10.1021/acsp Photonics.8b01306))

➤ 45% valley polarization, 30% valley coherence @Room Temperature



# Large valley contrasts in $WS_2/Gr$ (20 K)

\*Raman features



*Record valley coherence up to 60 % (10 %) in BN-capped  $WS_2/Gr$  (BN capped  $WS_2$ )*

E.Lorchat, S.Azzini, T.Chervy *et al.*, ArXiv:1804.06725 (doi: [10.1021/acsphotonics.8b01306](https://doi.org/10.1021/acsphotonics.8b01306))

# Conclusion and outlook

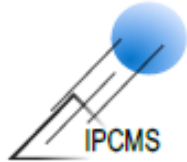
---

✓ 2D matter meets 2D light:

*many games to play at the interface between (chiral) nanophotonics, condensed matter physics and materials science*

- Interfacing 2D materials with chiral plasmonic resonators
- Probing dark excitonic states using surface plasmons
- Electrical and electromechanical control of chiral coupling
  
- Charge and energy transfer mechanism(s)
- Intervalley scattering mechanisms in TMD/Gr vs bare TMD

# Acknowledgements



*Etienne Lorchat  
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Florentin Fabre  
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Shaojun Wang (Eindhoven, NL)  
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TOULOUSE



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Xavier Marie*



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Kenji Watanabe*

*Funding:*

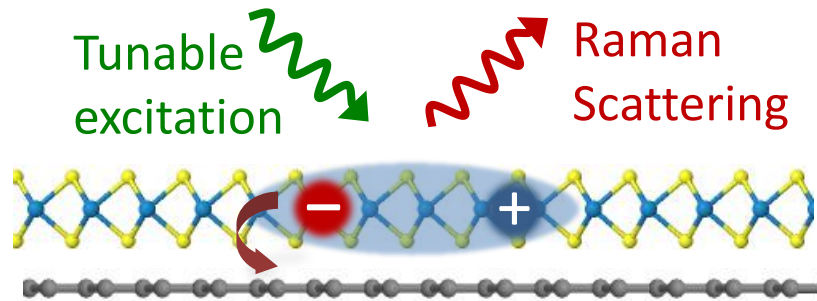


# Supplementary Slides

Net charge transfer in TMD-Gr heterostructures

General slides on heterostructures and on energy transfer

## *How about photoinduced charge transfer?*



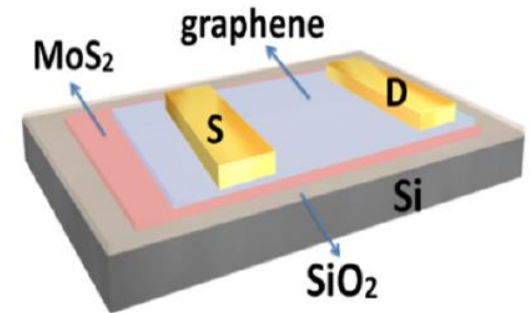
...study of net (and slow) electron transfer from TMD to Graphene (cf PRX 2018).  
This effect is likely extrinsic (not observable if we replace SiO<sub>2</sub> by hBN)  
but is of interest for photodetection/photogating (see next slide).

# Gr/TMD heterostructures: why the interest?

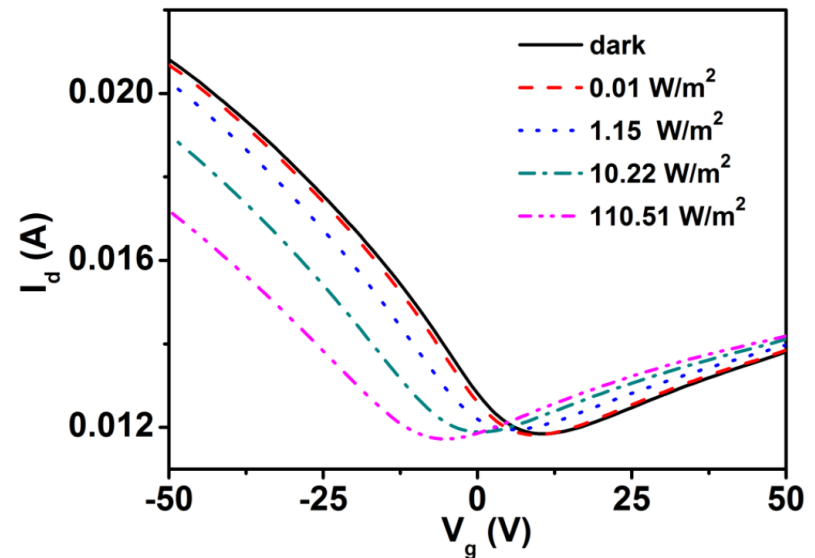
✓ Strong interlayer coupling  
(J. He et al., Nat Comm. 2014)

✓ Photogating/photodetection  
(W. Zhang et al., Sci. Rep. 2014)

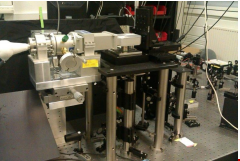
✓ ps-range photoresponse  
(M. Massicotte et al., Nat Nano 2016)



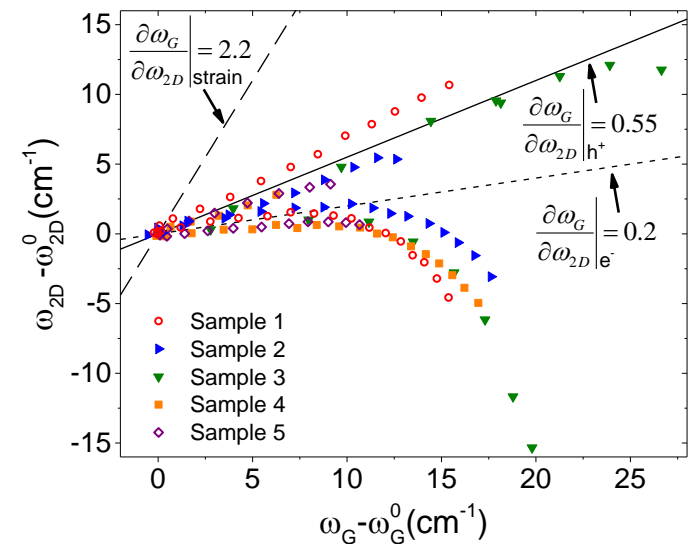
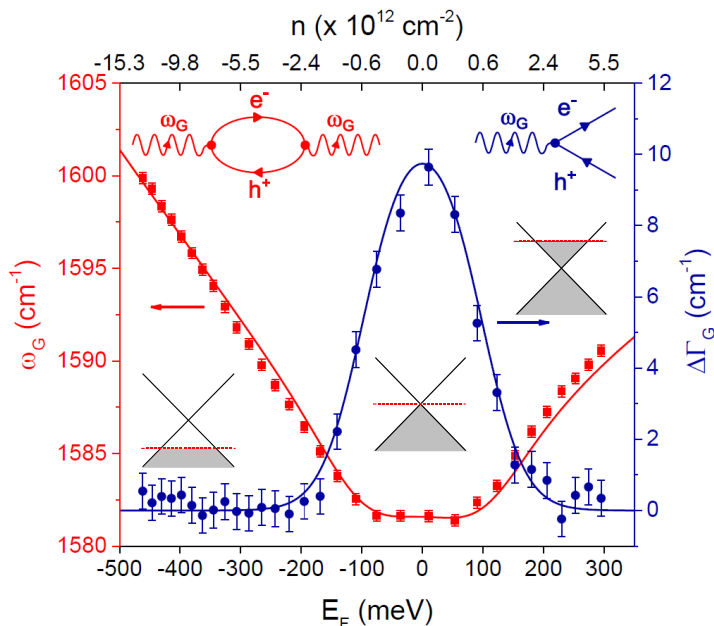
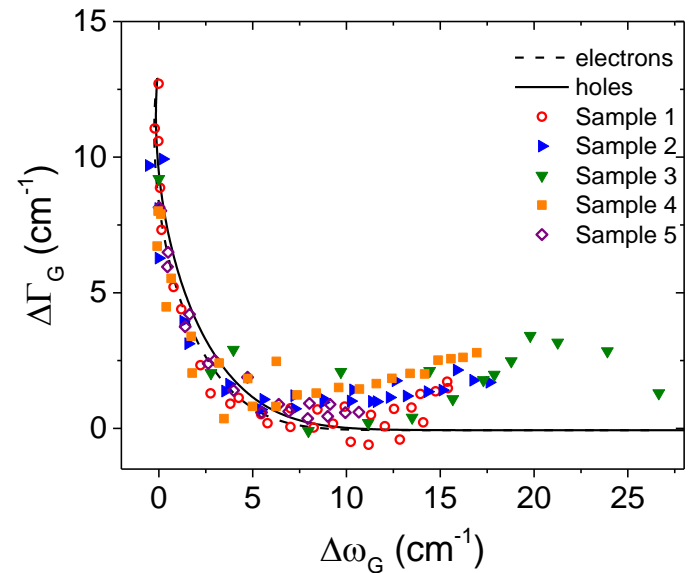
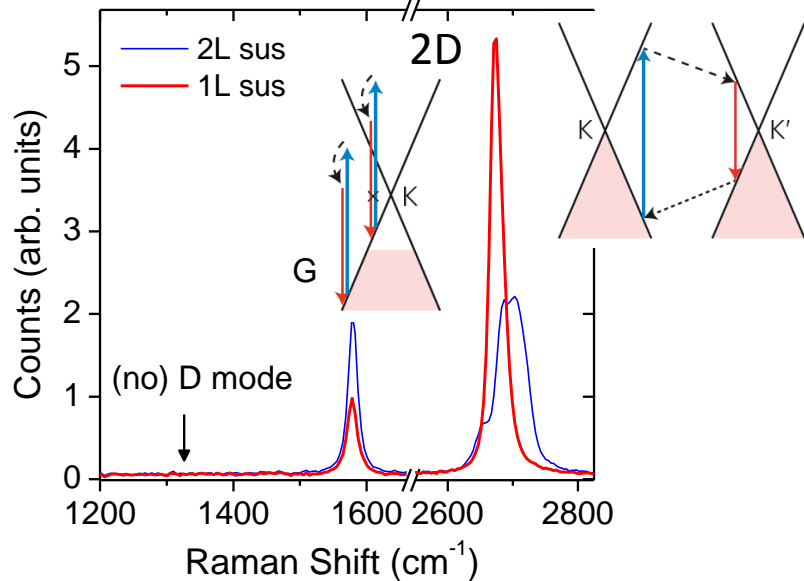
W. Zhang *et al.*, Sci. Rep. 2014 KAUST





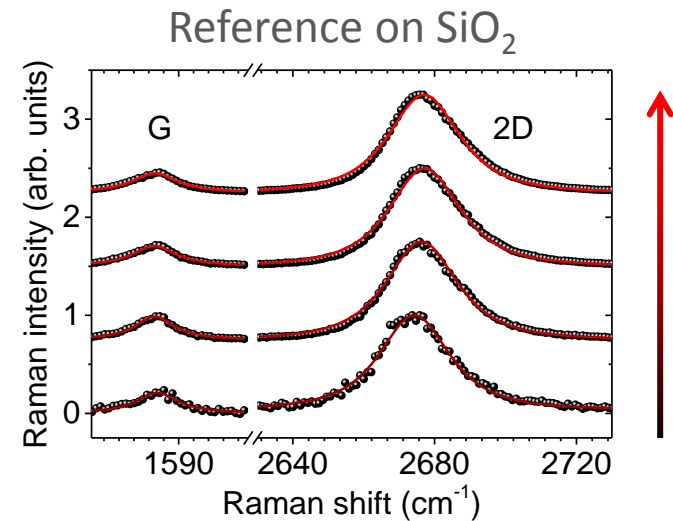
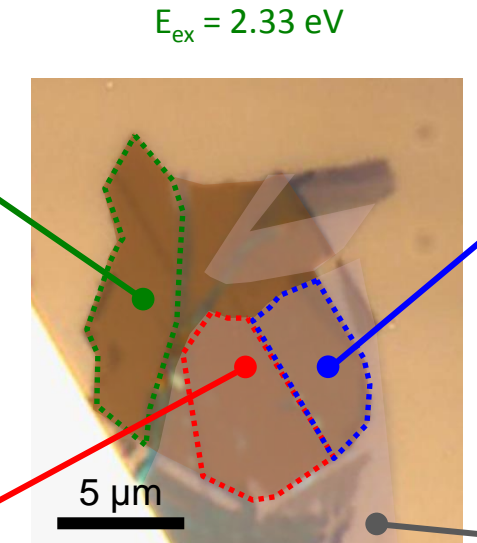
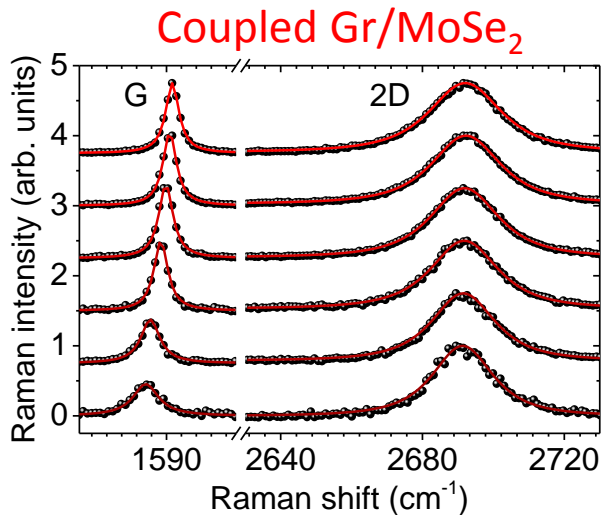
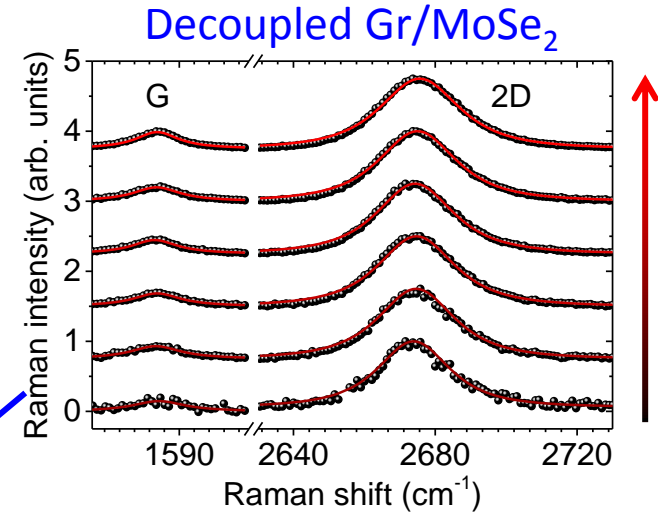
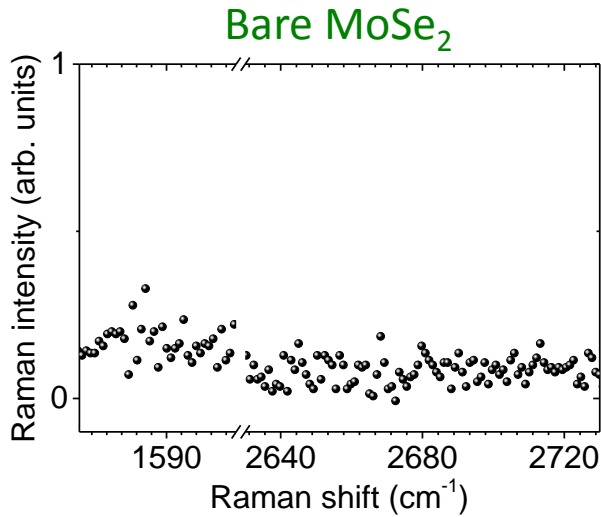


# Raman spectroscopy: a quantitative probe of doping



Data: G. Froehlicher & SB, PRB 2015. See also: A. Das *et al.*, Nat. Nano 2008  
S. Pisana *et al.*, Nat Mater 2007, J. Yan *et al.*, PRL 2007,...

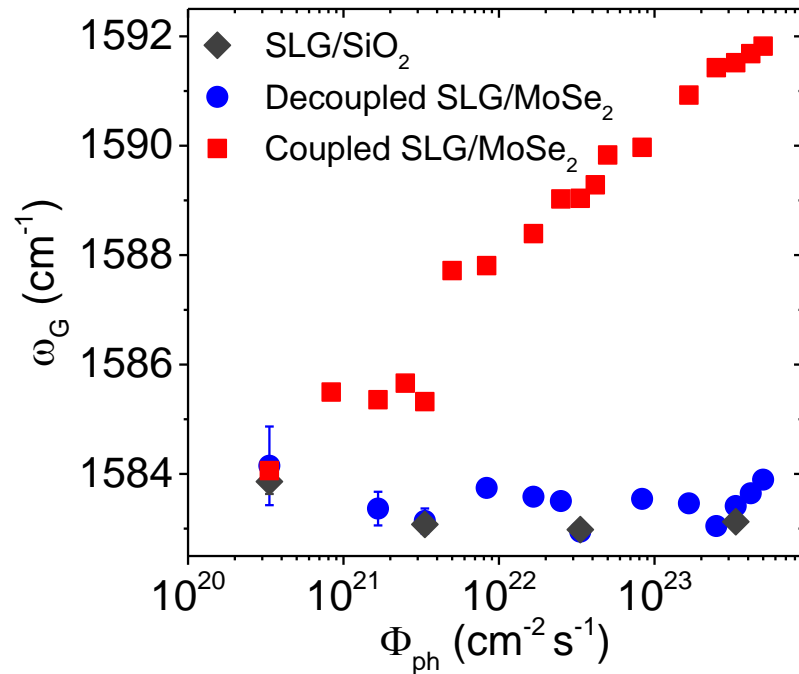
# Raman response vs photon flux (1)



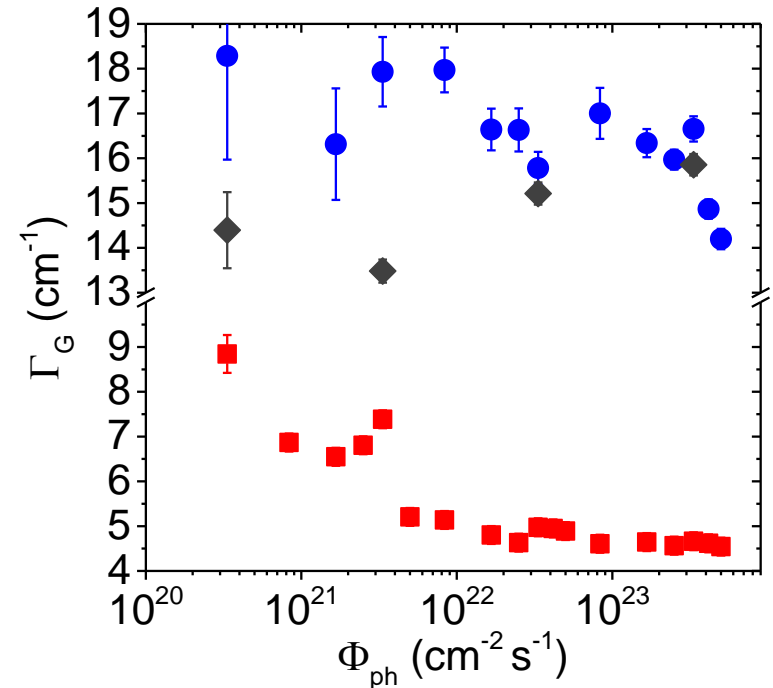
$\Phi_{\text{ph}}$  increases

# Raman response vs photon flux (2)

## G-mode frequency



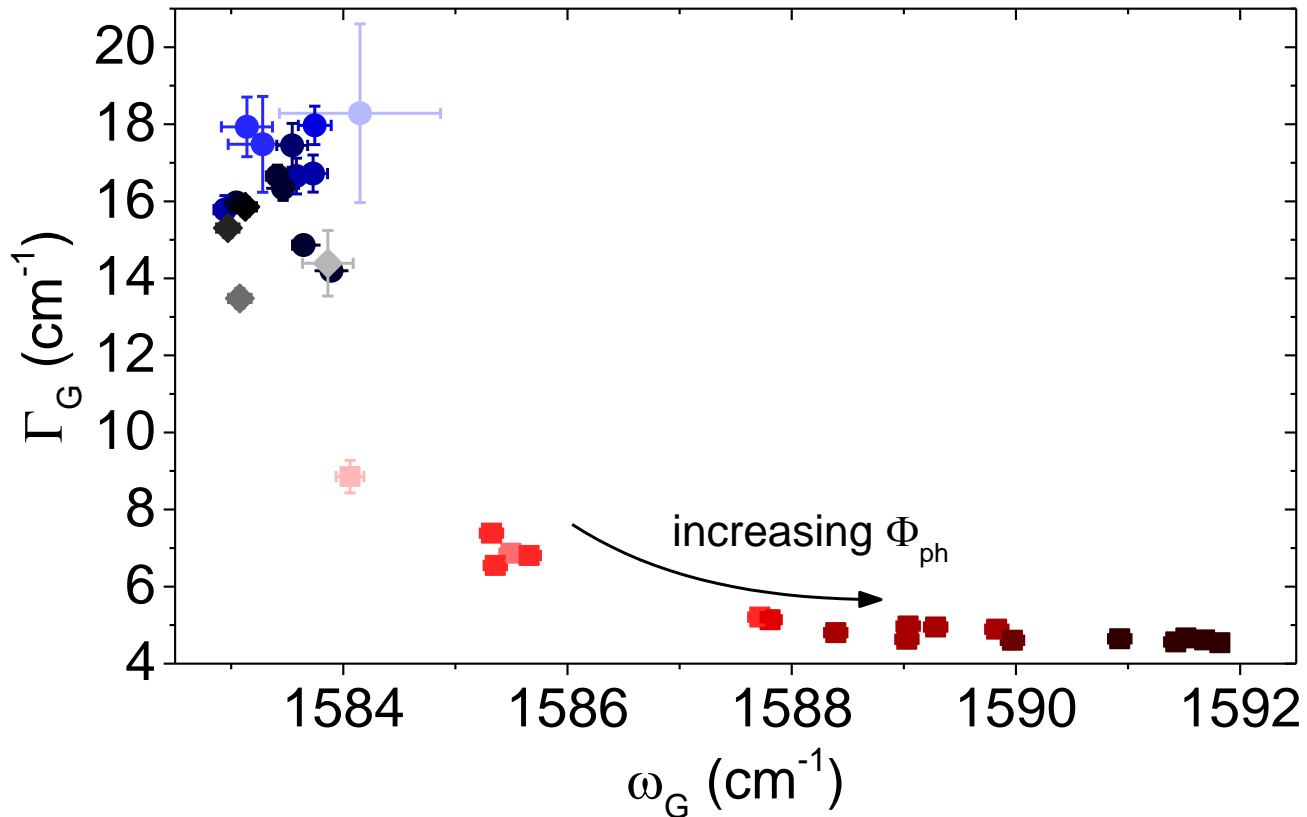
## G-mode FWHM



➡ Clear signatures of a net photoinduced charge transfer

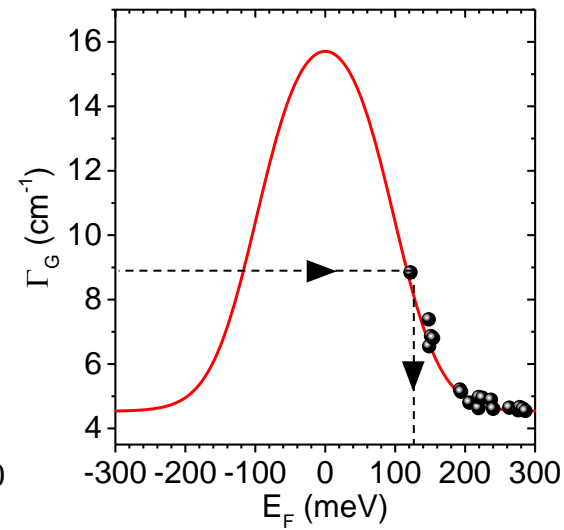
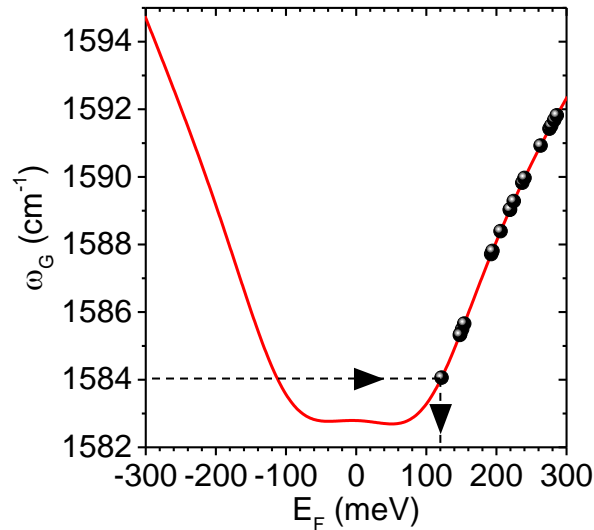
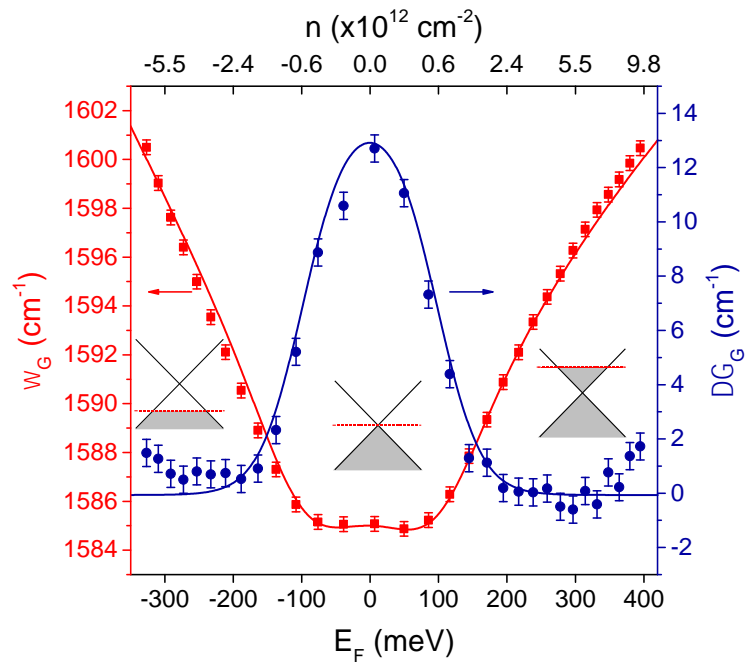
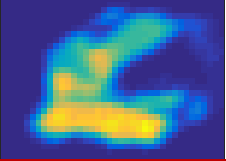
# Raman response vs photon flux (2)

## Width-Frequency Correlation





# Quantifying photoinduced doping



- Evidence for net photoinduced electron transfer
- Extrinsic effect – slow dynamics

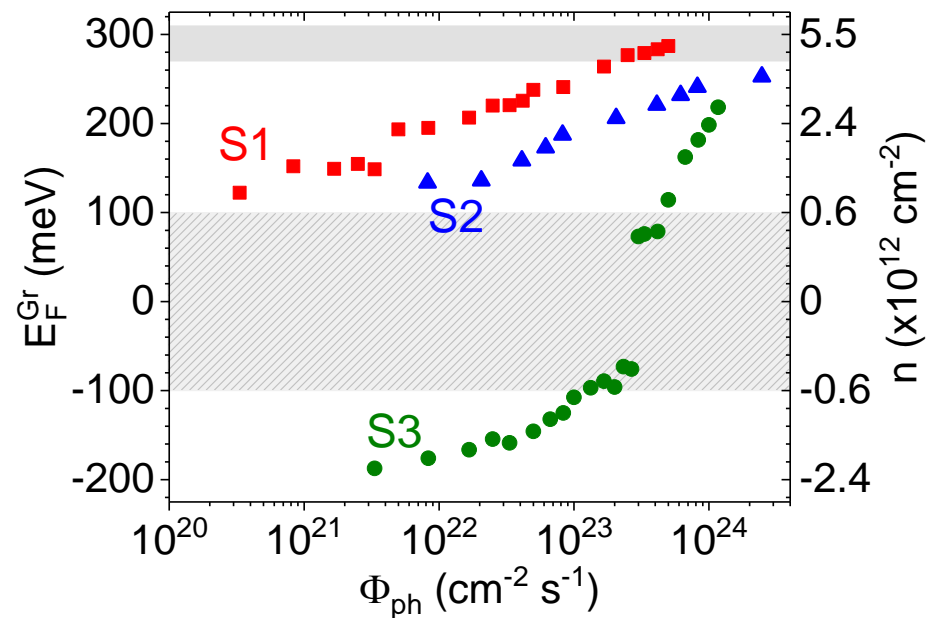
G. Froehlicher and S. Berciaud, PRB **91**, 205413 (2015)

G. Froehlicher, E. Lorchat, S. Berciaud, Phys. Rev. X **8**, 011007 (2018)

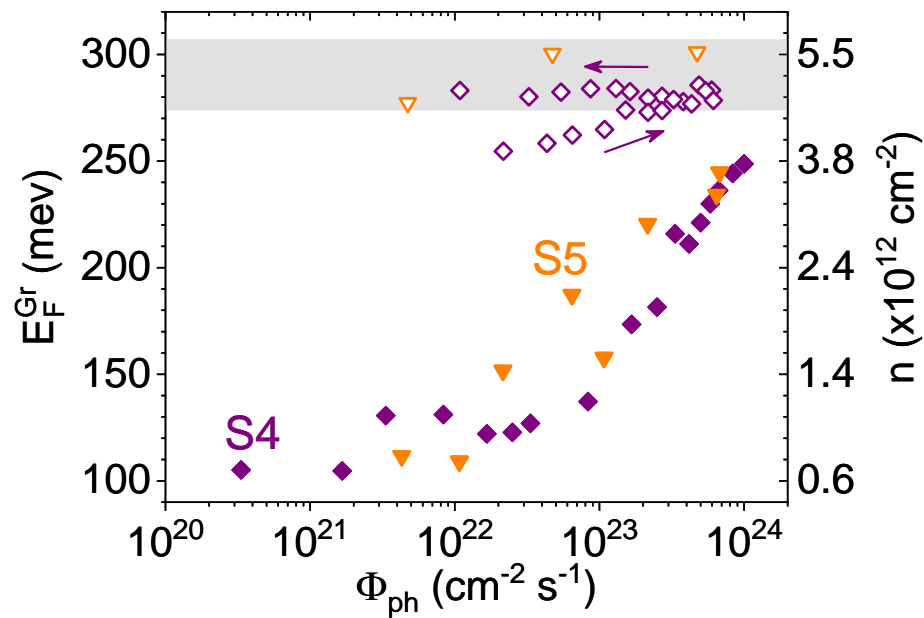


# Reproducibility and environmental effects

Several Gr/MoSe<sub>2</sub>/SiO<sub>2</sub> samples  
Ambient AIR



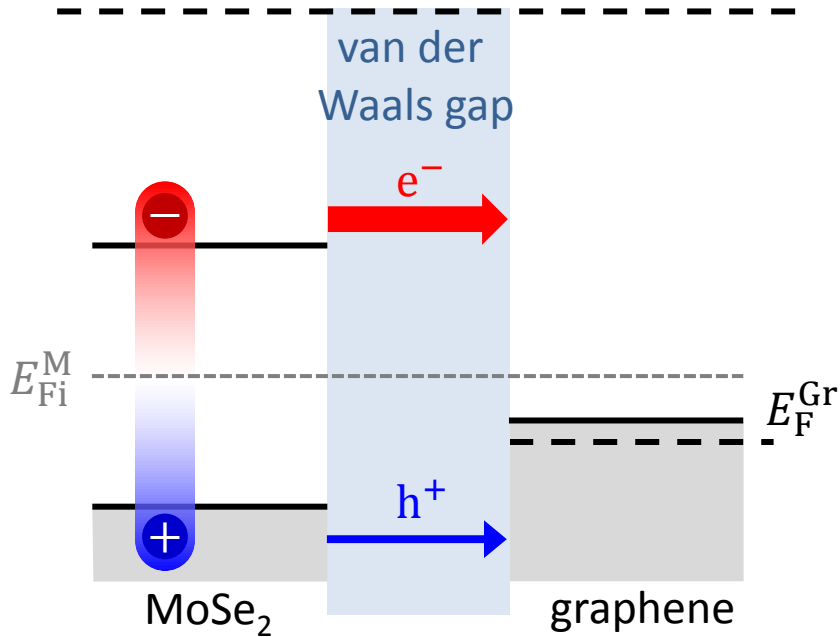
Gr/MoSe<sub>2</sub>/SiO<sub>2</sub> vs MoSe<sub>2</sub>/Gr/SiO<sub>2</sub>  
Air (full) vs vacuum (open)



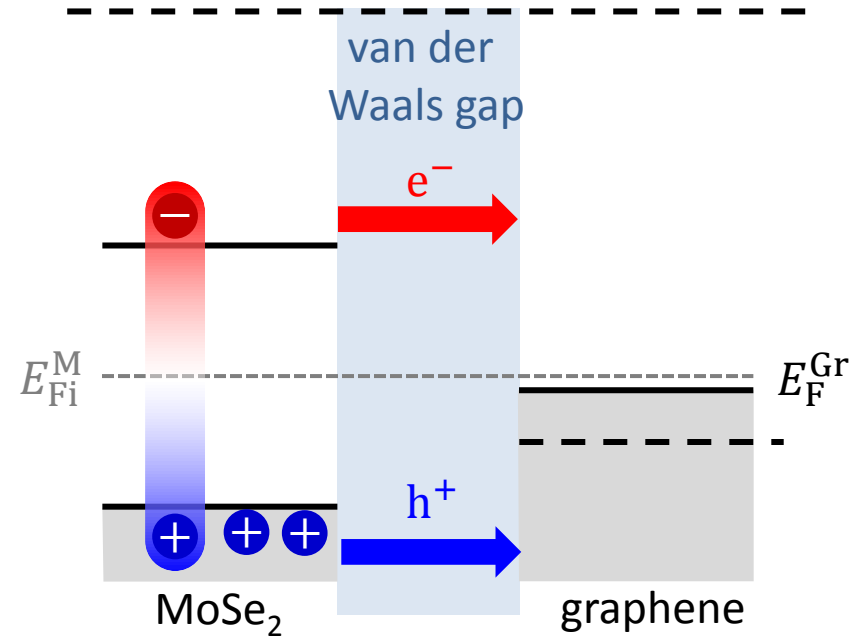
- *Electron trapping by molecular adsorbates in air*
- *Direct saturation under vacuum*

# Microscopic mechanism (in vacuum)

Light on,  $t=0$

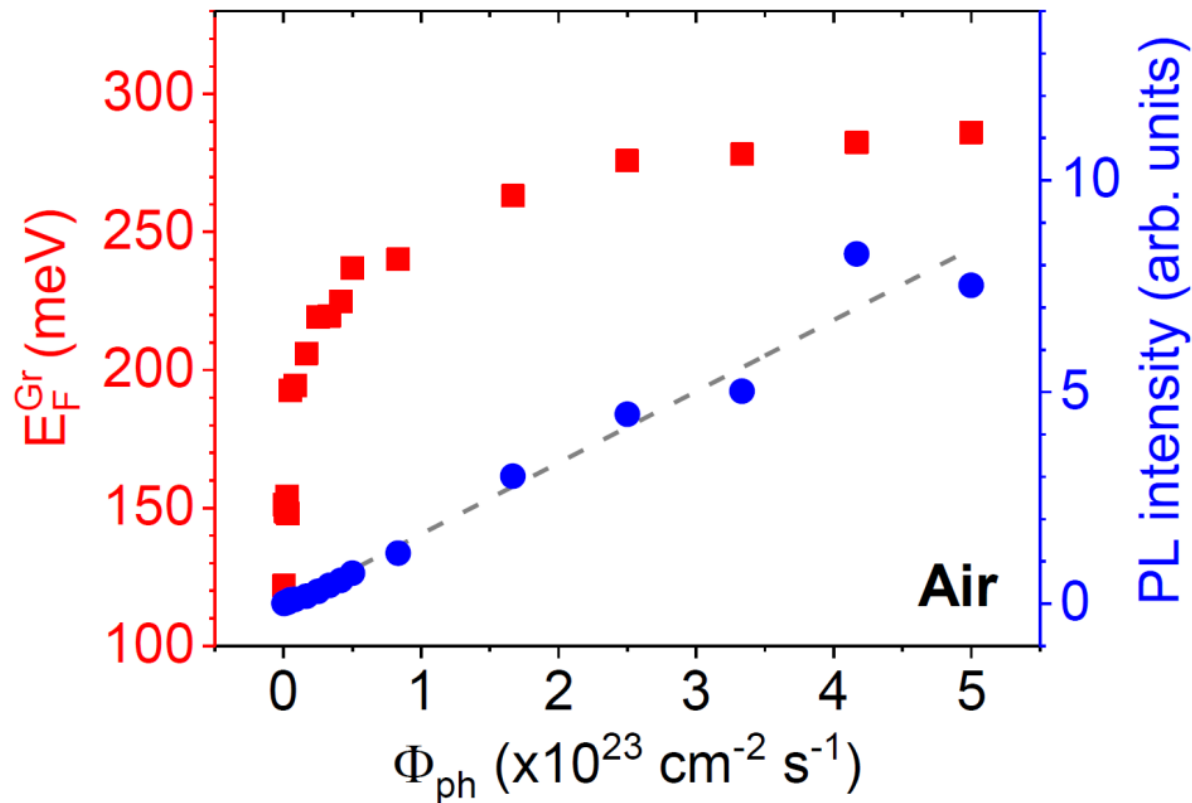


Light on,  $t \rightarrow \infty$



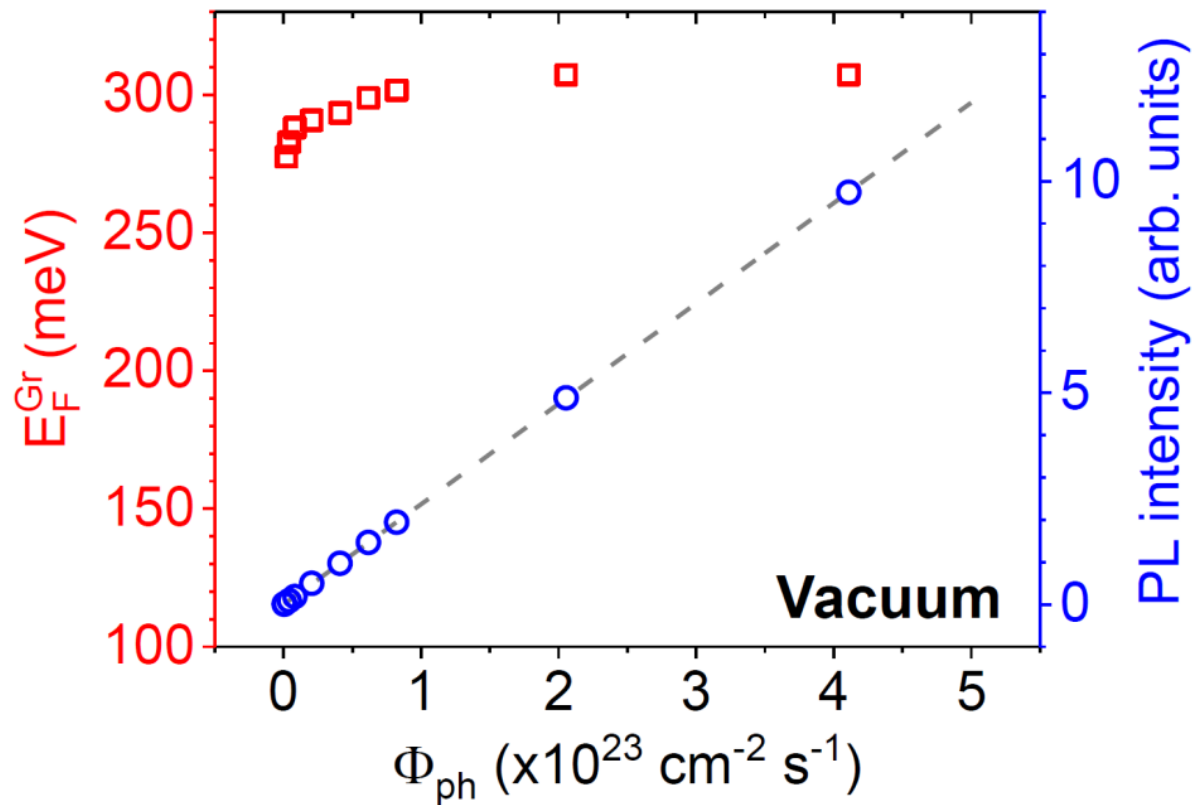
- ✓ *Balanced electron and hole currents at saturation*
- *Intrinsic mechanism?*
- *Optical determination of band offsets?*

# Recap: Fermi level and PL intensity



- Exciton dynamics in MoSe<sub>2</sub> is largely independent of the electron and hole transfer efficiencies  
→ Strong hint for dominant energy transfer

# Recap: Fermi level and PL intensity



- Exciton dynamics in  $\text{MoSe}_2$  is largely independent of the electron and hole transfer efficiencies  
→ Strong hint for dominant energy transfer

# Partial conclusion

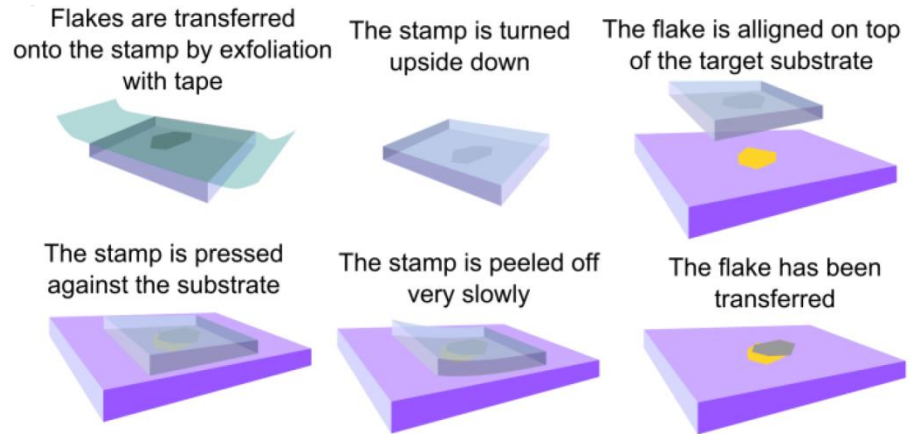
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- ✓ ***Strong interlayer coupling in Gr/TMD heterostructures***
- ✓ ***Saturation of the net electron transfer***
- ✓ ***Highly efficient (sub)-picosecond energy transfer***
- ***Förster vs Dexter energy transfer?***
- ***Electrical control of charge and energy transfer***
- ***Implications for optoelectronics and optospintronics***

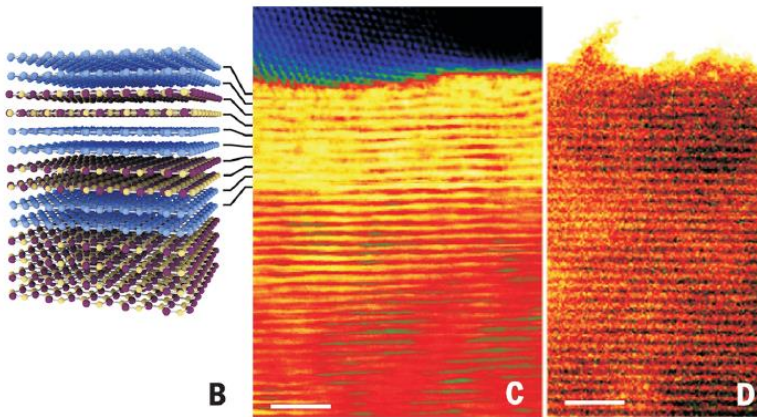
More info: G. Froehlicher, E. Lorchat, S. Berciaud, Phys. Rev. X **8**, 011007 (2018)

# van der Waals Heterostructures

- ✓ No dangling bounds
  - ✓ No lattice mismatch issues
  - ✓ Rotational degree of freedom
- 2010 : Graphene on hBN
  - 2017 : wet or dry transfer, pick up and lift,...
  - Numerous possibilities!



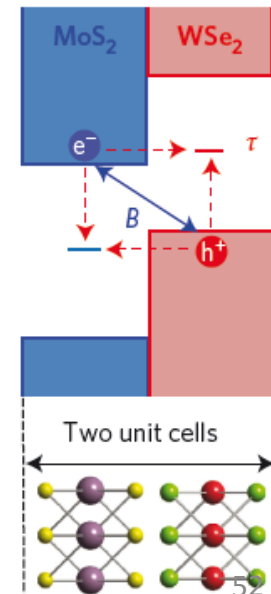
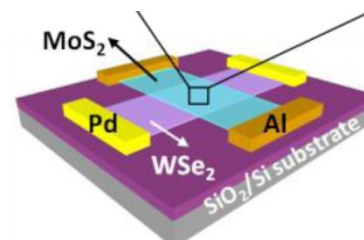
Castellanos-Gomez *et al.* 2D Materials **1** 011002 (2014)



Haigh, Gorbachev *et al.*, Nature Materials 2012  
Manchester Group

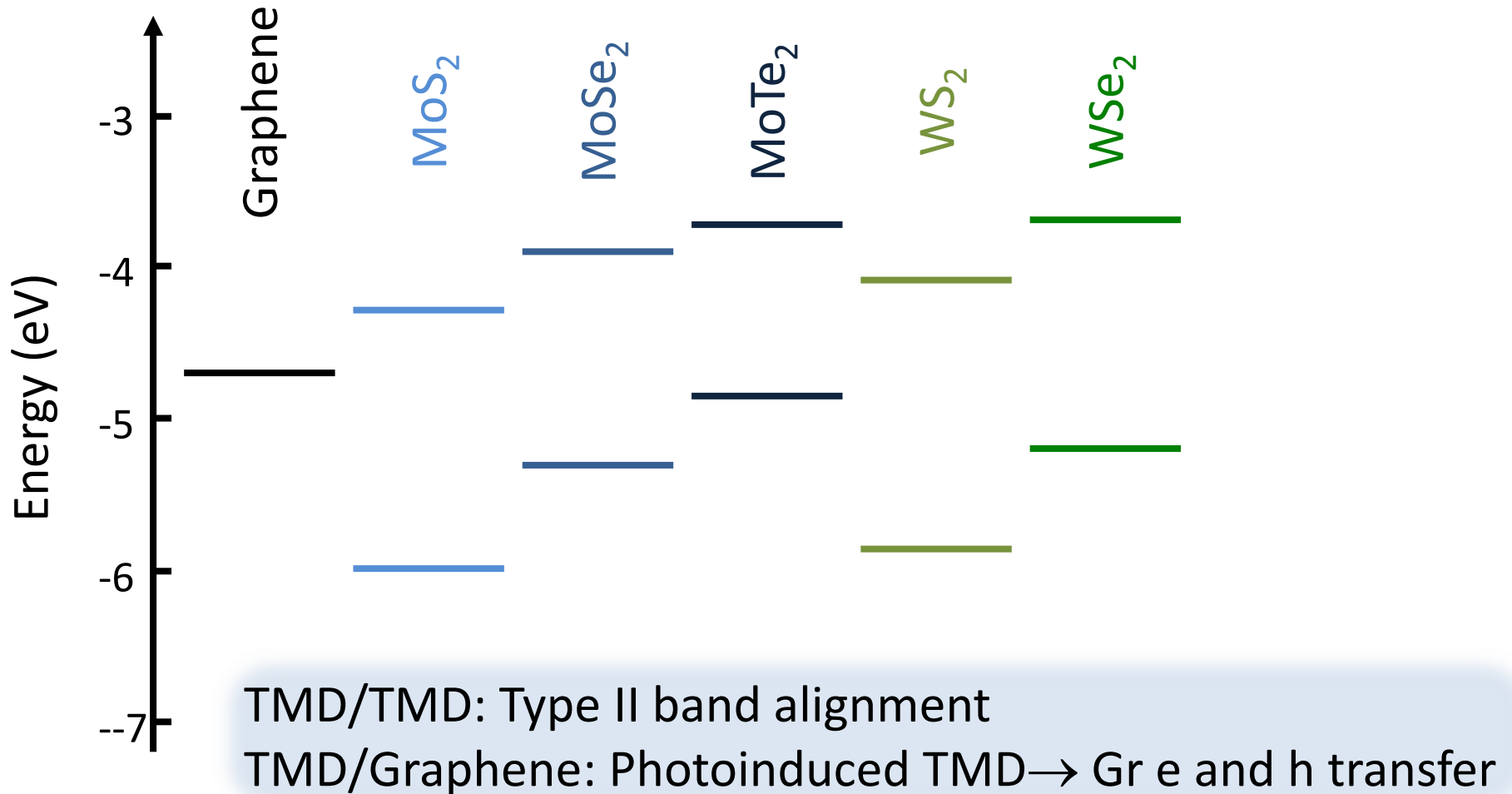
## Atomically thin *p-n junctions*

C-H Lee *et al.*  
Nat. Nano (2014)  
(Columbia)





# Band offsets in 2D materials

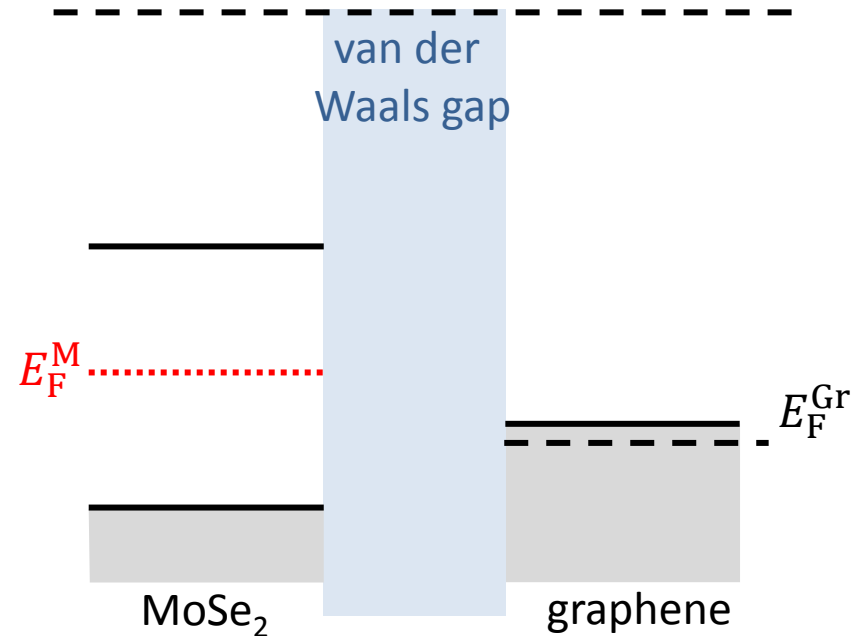
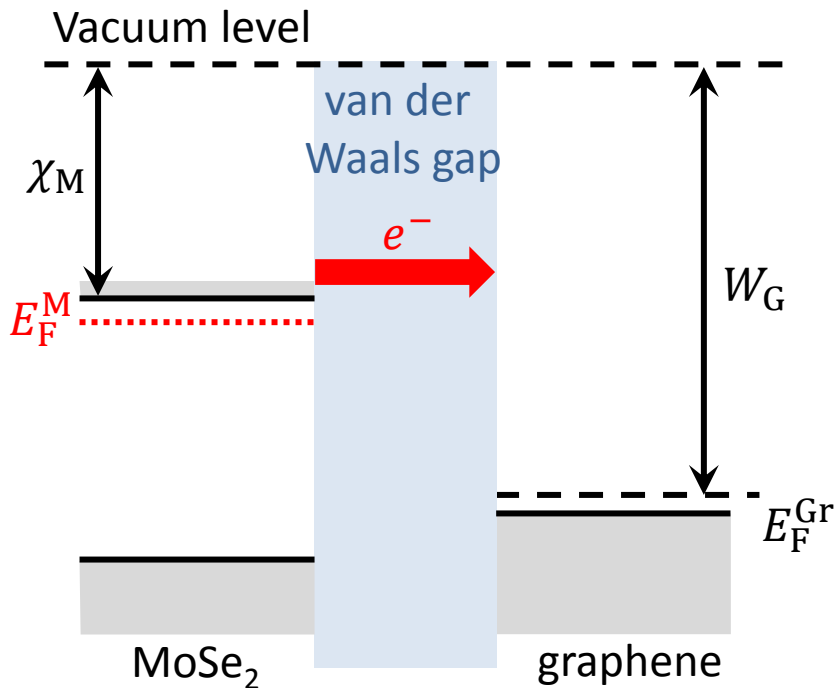
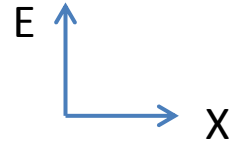


TMD: Y. Liang *et al.*, APL **103**, 42106 (2013), M. Ugeda *et al.*, Nat. Mater. **5**, 1091 (2014)

Graphene: Y.-J. Yu *et al.*, Nano Lett. **9**, 3430 (2008)

# Microscopic Mechanism

*In the dark*



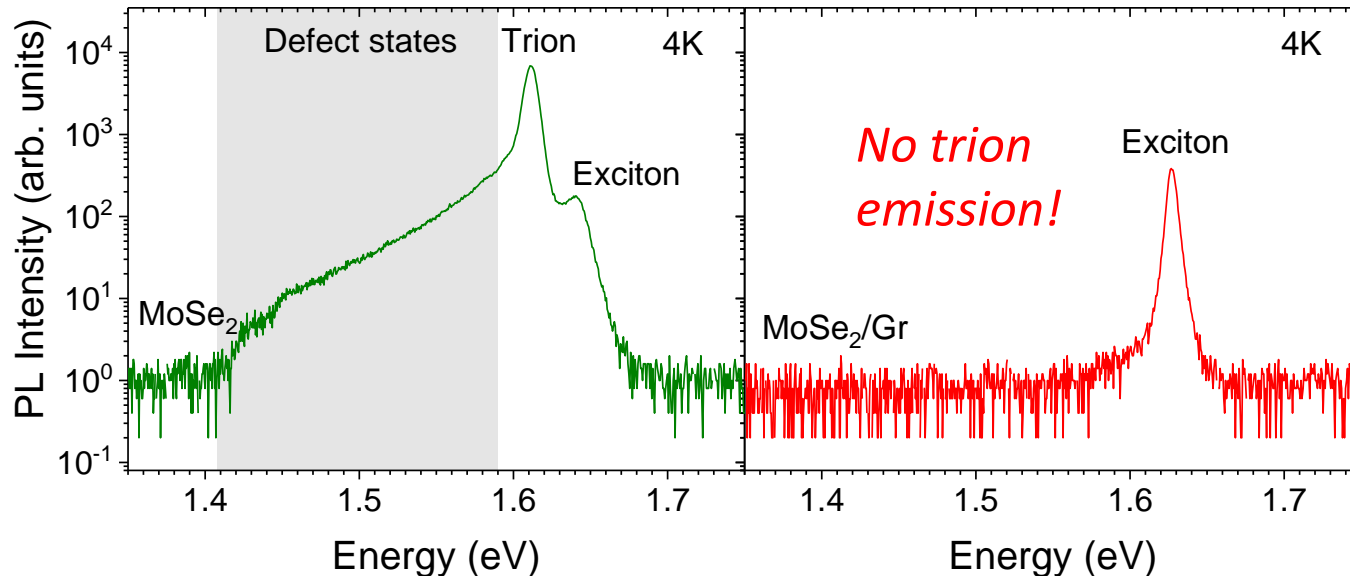
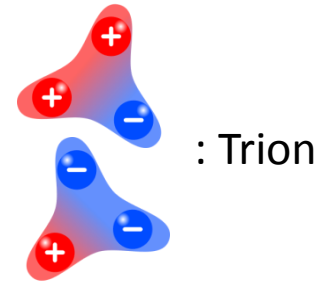
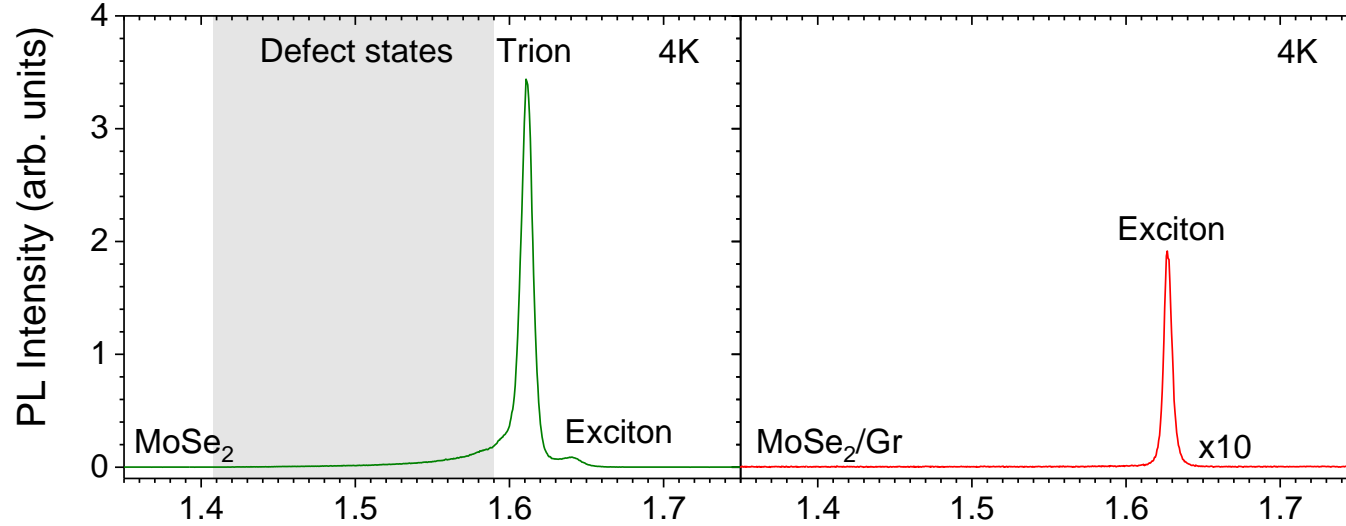
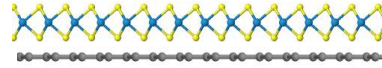
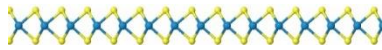
*Before contact:*

- n-doped MoSe<sub>2</sub>
- Weakly doped graphene

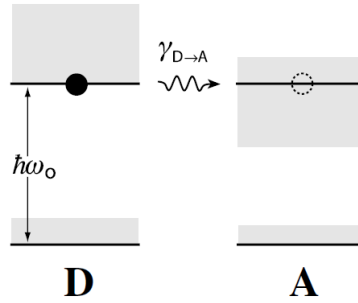
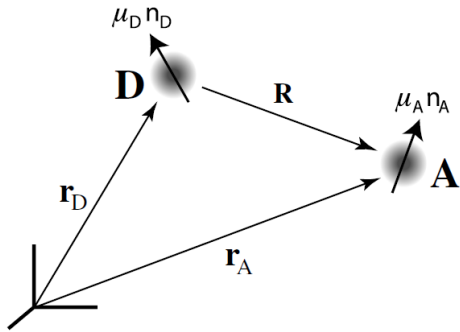
*After contact (in the dark):*

- Neutral MoSe<sub>2</sub>
- n-doped graphene

# Outlook: low-temperature photoluminescence



# Förster energy transfer: near field dipole-dipole interaction



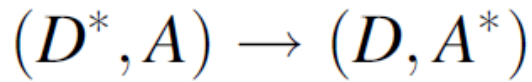
$$\frac{\gamma_{D \rightarrow A}}{\gamma_0} = \frac{P_{D \rightarrow A}}{P_0}$$

$$\mathbf{E}_D = \frac{1}{4\pi\epsilon_0} \left[ \cancel{k^2 (\mathbf{r} \wedge \boldsymbol{\mu}_D) \wedge \mathbf{r} \frac{e^{ikr}}{r^2}} + \left( \frac{3\mathbf{r}(\mathbf{r} \cdot \boldsymbol{\mu}_D)}{r^2} - \boldsymbol{\mu}_D \right) \left( \frac{1}{r^3} - \cancel{\frac{ik}{r^2}} \right) e^{ikr} \right]$$

$$P_{D \rightarrow A} = -\frac{1}{2} \int_{V_A} \text{Re}\{\mathbf{j}_A^* \cdot \mathbf{E}_D\} dV \approx \frac{\omega_0}{2} \text{Im}\{\alpha_A\} |\mathbf{n}_A \cdot \mathbf{E}_D(\mathbf{r}_A)|^2$$

$$\frac{\gamma_{D \rightarrow A}}{\gamma_0} = \left[ \frac{R_0}{R} \right]^6 \quad R_0^6 = \frac{9c^4 \kappa^2}{8\pi} \int_0^\infty \frac{f_D(\omega) \sigma_A(\omega)}{n^4(\omega) \omega^4} d\omega$$

# Förster and Dexter energy transfer



$$U = \langle \Psi_i | \hat{V} | \Psi_f \rangle$$

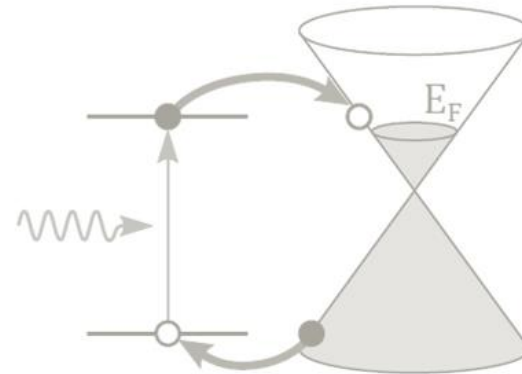
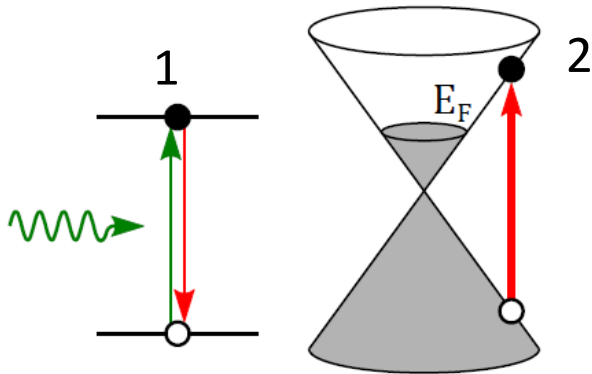
$$U = \langle \Psi_{D^*}(1) \Psi_A(2) | \hat{V} | \Psi_D(1) \Psi_{A^*}(2) \rangle - \langle \Psi_{D^*}(1) \Psi_A(2) | \hat{V} | \Psi_D(2) \Psi_{A^*}(1) \rangle$$

*Coulomb (FRET) term*

- ✓ 'Long' range (power law)
- ✓ Implies spectral overlap

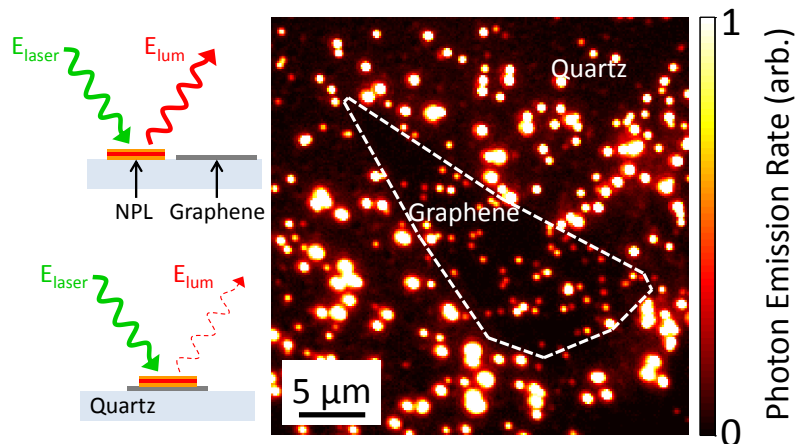
*Exchange (Dexter) term*

- ✓ Short range (exponential, idem CT)
- ✓ Implies overlap of molecular orbitals



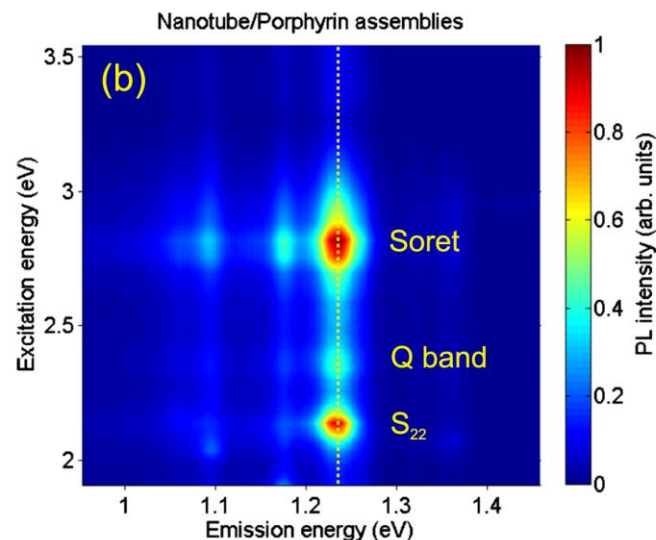
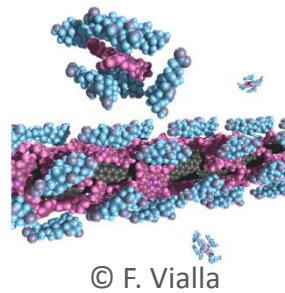
# Energy transfer in low-dimensional heterostructures

## Nanoscale emitter/graphene



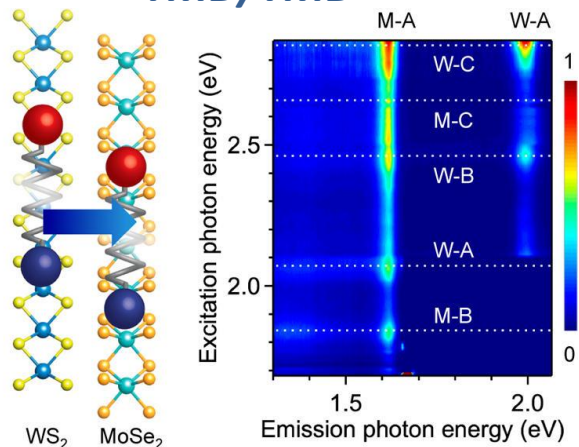
- Z. Chen *et al.*, ACS Nano **4**, 2964 (2010) (QD-Gr)  
 F. Federspiel *et al.*, Nano Lett. **15**, 1252 (2015) (QD-Gr, NPL-Gr)  
 L. Gaudreau *et al.*, Nano Lett. **13**, 2030 (2013) (Dye-Gr)

## Molecules/nanotubes



C. Roquelet *et al.*, APL **97**, 141918 (2010)

## TMD/TMD



D. Kozawa *et al.*, Nano Lett. **16**, 4087 (2016)

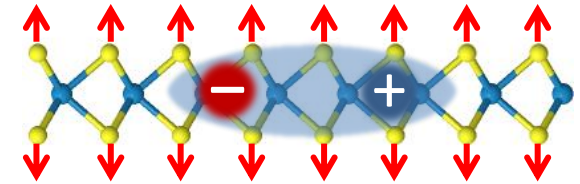
*Interlayer energy transfer has been largely overlooked in TMD/Gr*



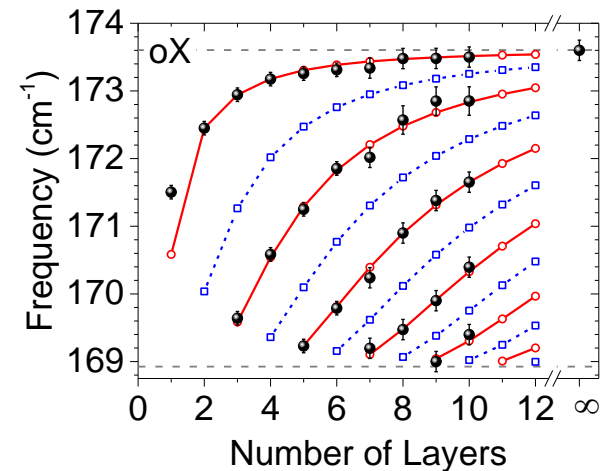
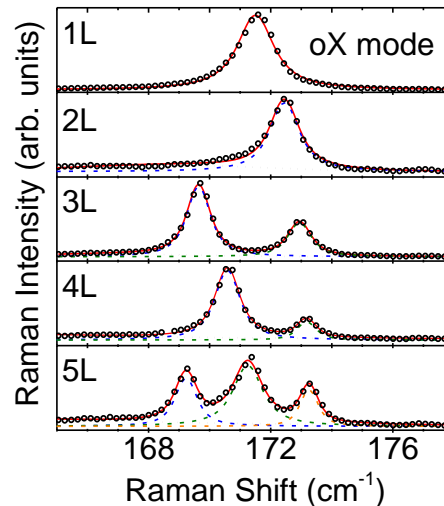
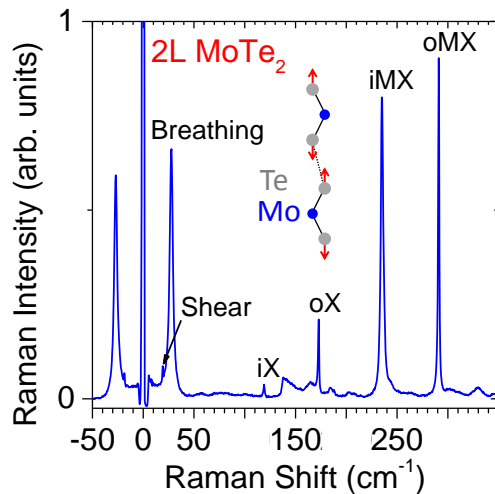
# 2D Materials at IPCMS



- Optical spectroscopy
- Phonons, excitons and their coupling(s)



✓ Interlayer interactions: Davydov splitting and unified description of the phonon modes



2H TMD - Froehlicher *et al.*, Nano Lett. 2015, Miranda *et al.*, Nano Lett. 2017. Coll: L. Wirtz group, Uni. Luxembourg

1T' TMD - Lorchat *et al.* ACS Nano 2016 (ReS<sub>2</sub> and ReSe<sub>2</sub>)

See also Froehlicher *et al.*, J. Raman Spec. 2018 (special issue on 2D materials)